MAGNIV DEEP DIVE TRAINING

RAYMOND TANG

2019.12

Agenda

- MagniV Family Overview
- S12Z Core Introduction
- Peripheral Introduction (Selected)
  - CPMU
  - Power Domain
  - PMF, PTU and ADC
  - GDU
- Case Sharing
- QA

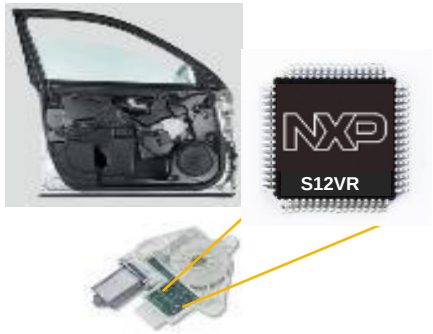
MAGNIV FAMILY OVERVIEW

MagniV Family Overview

S12 MagniV simplifies system design by integrating High-Voltage (HV) analog features onto MCUs for automotive applications

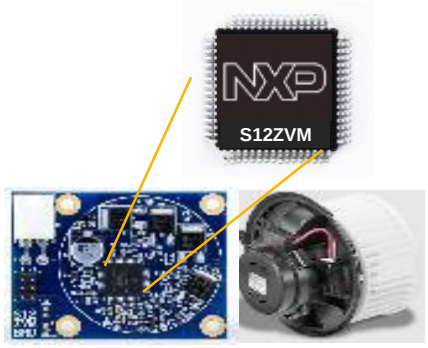
Motor Control focus

S12VR
Relay driven motors



- Window lift
- Sunroof
- Power doors

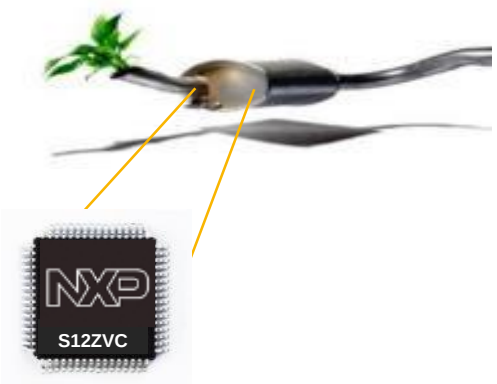
S12ZVM
BLDC/DC motors



- Fuel pump
- Oil pump
- Fans
- Wipers

Sensor Interface focus

S12ZVC
CAN nodes



- Safety sensors
- Emission sensors
- Gear shift

S12ZVL
LIN Nodes

- Steering wheel switches
- Door modules
- Sensors

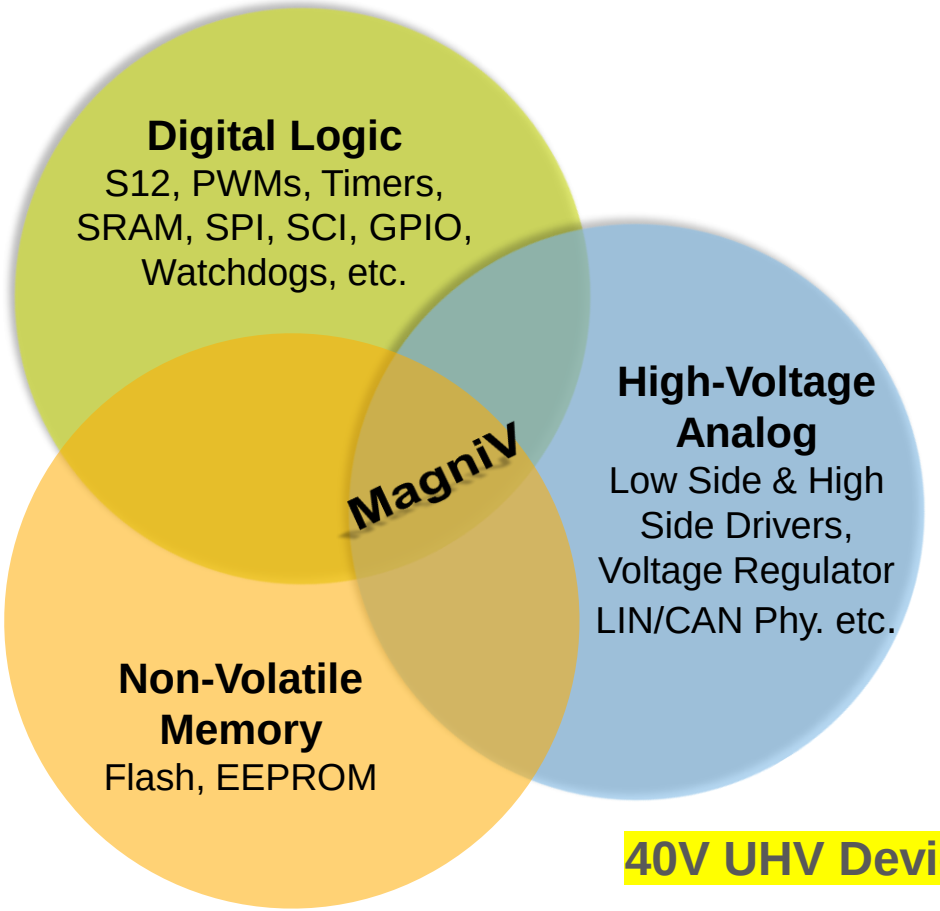
Reduced PCB Space

Reduced Bill of Material

Improved manufacturing efficiency and quality

Simplified development

MagniV Family Overview - Technology



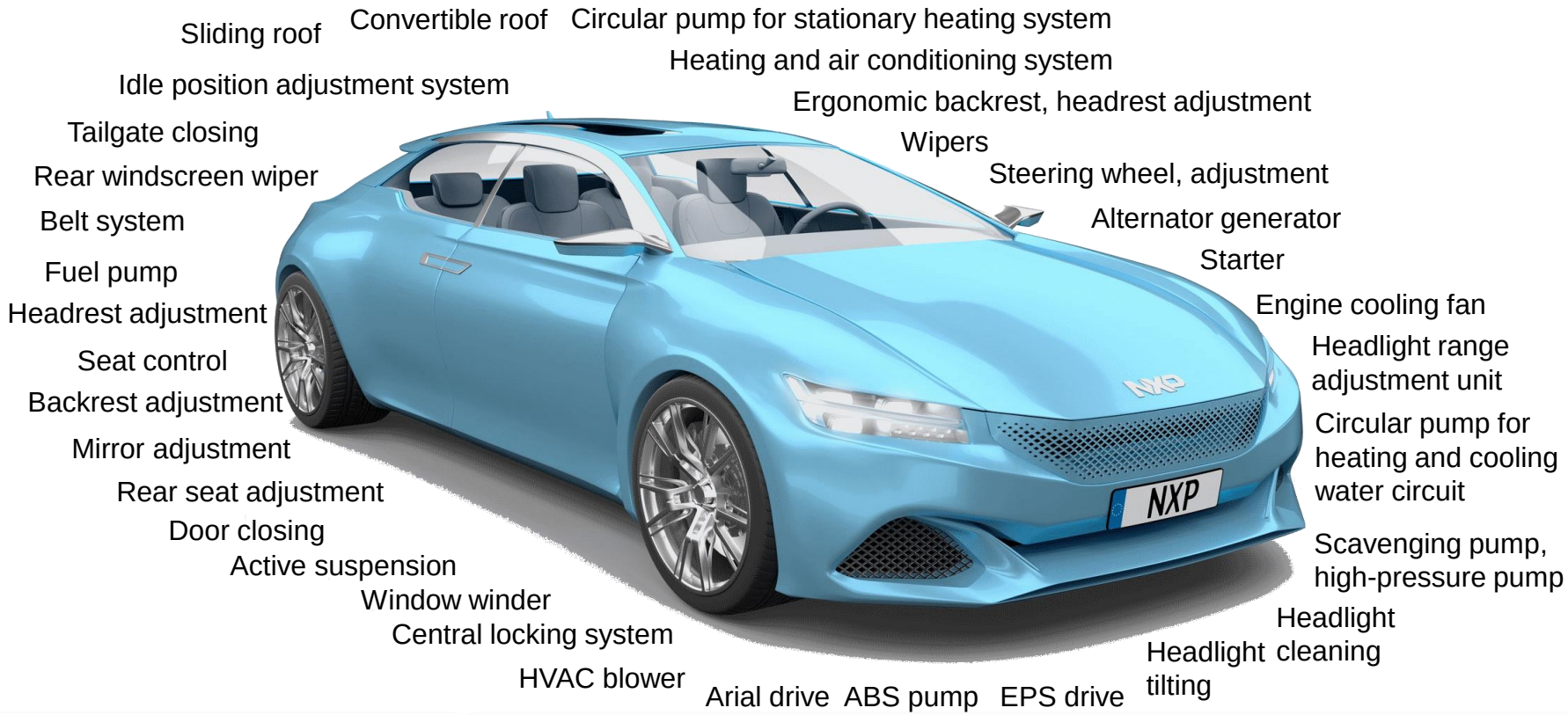
40V UHV Devices

Existing
Low Leakage 180nm CMOS+NVM

MagniV Family Overview - Motor Control

Electric Motors

Electric motors shipped into automotive applications increasing from 2.5 billion (‘13) to 3 billion (‘15)*



~30 electric motors per vehicle

S12 MagniV covering most common motors:
BL motors continuously/often in operation
DC motors rarely in operation

* according report from IHS Inc

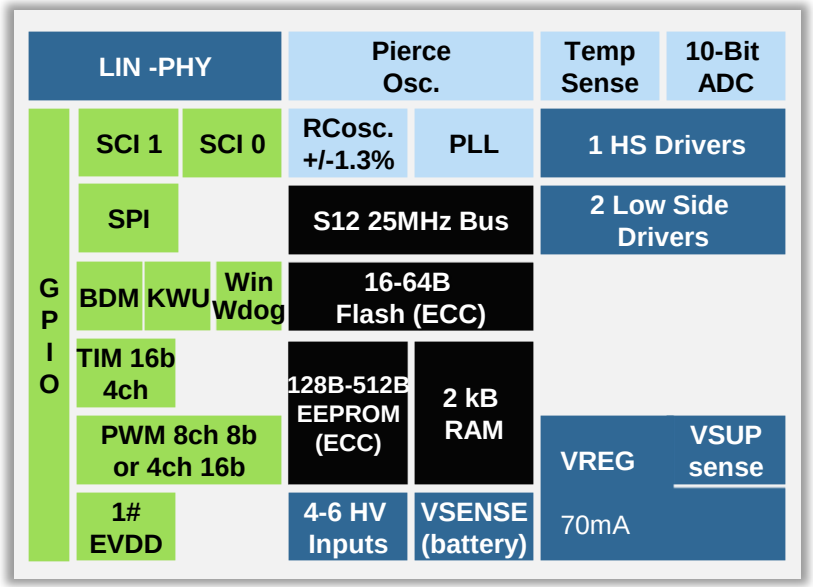
MagniV Family Overview - Motor Control Products

MagniV Family Overview - S12VR

Relay based DC Motors

Key Features:

- S12 (25 MHz max) 16-bit CPU compatible with the S12G family and MM912 solutions.
- Voltage Regulator operating directly from car battery (No ext regulator needed) capable to drive 20mA to drive offchip components (eg powering Hall sensor))
- LIN Physical Layer: LIN 2.x / J2602 compliant ; +/- 8kV ESD capability
- Up to 512B EEPROM with ECC, 4 byte erasable
- 2 Low-Side drivers with active clamps to drive relays (inductive load) for bi-directional brushed DC Motors
- Up to 2 HS drivers: For indicator LED and Switch supply
- 4 High Voltage Inputs: 12V Inputs for Switch Monitoring, ESD-protected, can be used for wake-up/interrupts or 12V analog inputs routed to ADC internally through selectable divider ratio.
- On chip RC Oscillator; trimmed to +/- 1,3% tolerance over full temperature range



Target Applications

- Automotive power window lift / sunroof with antipinch
- Any relay driven DC motors
- LIN slaves with space constraints

Family options:

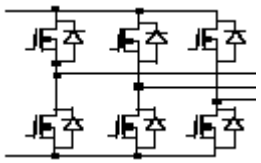
- Flexible Flash Options: 16kB to 64kB Flash
- Packaging: 32-LQFP or 48-LQFP
- C / V / M Temperature options (up to 125°C Ta)

MagniV Family Overview - S12ZVM *(Carcassonne/Obidos/VMC256)*

BLDC/PMSM/SR motor control

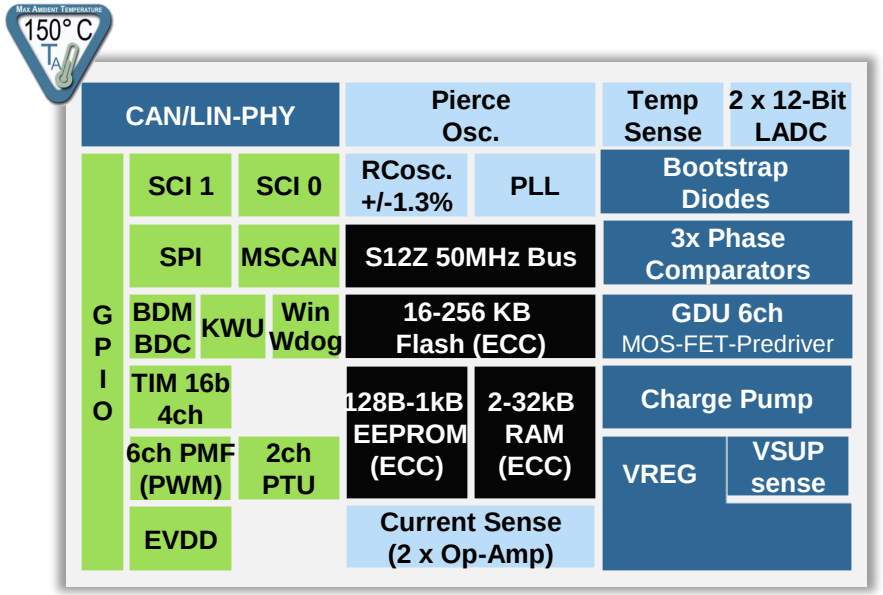
Key Features:

- S12Z CPU @ 50MHz bus speed
- 6ch Gate Drive Unit (GDU) with 50-150nC total Gate Charge drive capability, incl charge pump for High-Side, Bootstrap diodes for charging external bootstrap capacitors
- Embedded VREG with switchable 5V/20mA sensor supply
- LIN PHY, LIN2.1 / 2.2 / J2602 compliant
- CAN-PHY
- Dual 12bit list-based ADC (LADC), synch with PWM through Programmable Trigger Unit (PTU)
- 2x Op-amp for current sensing



Target applications:

- Sensorless BLDC or PMSM motor control
- Switched Reluctance Motor
- Bidirectional DC motors (H-Bridge)
- Various pumps (oil, fuel, water, vacuum)
- Cooling fan, HVAC blower, Turbocharger



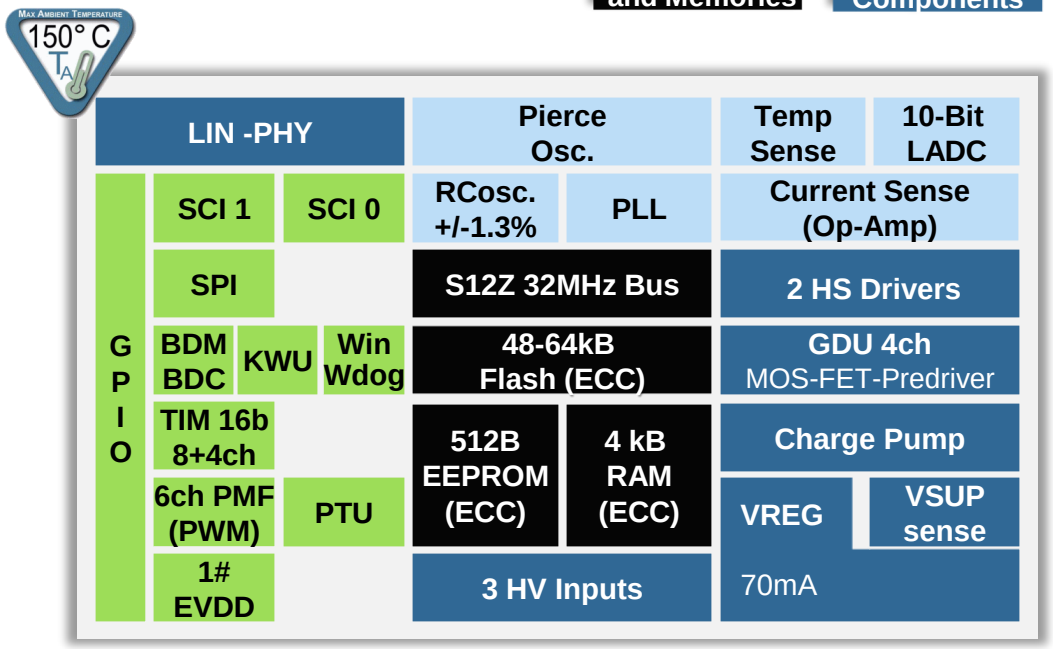
Options:

- Package: 64-LQFP-EP, 48 LQFP-EP, 80-LQFP-EP
- Memory: 16kB / 32kB / 64kB / 128kB / 256kB Flash
- Spec-Options:
  - L with LIN phy
  - C with CAN-PHY (256kB only)
  - C with 2nd Vreg for external CAN phy (128/64kB)
  - " " with High Voltage PWM-communication interface
- Temperature: V / M / W (up to 150°C Ta per AEC-Q100 Grade 0)

MagniV Family Overview - S12ZVMB

LIN based Integrated H-Bridge driver

Digital Components | 5V Analogue Components | MCU Core and Memories | High-Voltage Components

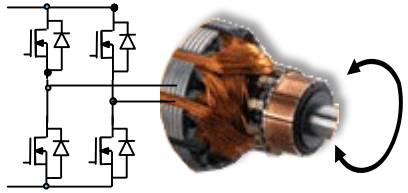


Key Features:

- S12Z CPU @ 32MHz bus speed
- VREG + 5V/20mA switchable sensor supply
- LIN PHY, LIN2.1 / 2.2 / J2602 compliant
- High Voltage Inputs (HVI) with internal connection to ADC for analog 12V measurements
- High-Side Drivers for switch panel and LED
- H-Bridge Gate Pre-Driver for 4-NMOS control (Gate Charge 50-80nC)

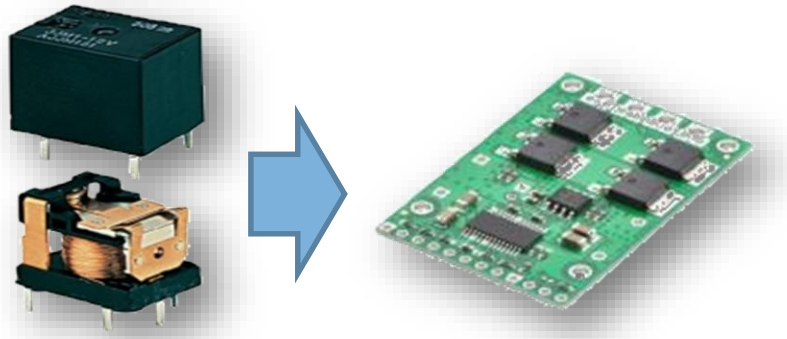
Target applications:

- Windowlift / Sunroof
- LIN-controlled Valves for gases / liquids (EGR-control)
- Seat-position, Lordosis
- Belt pretentioner, prefetcher



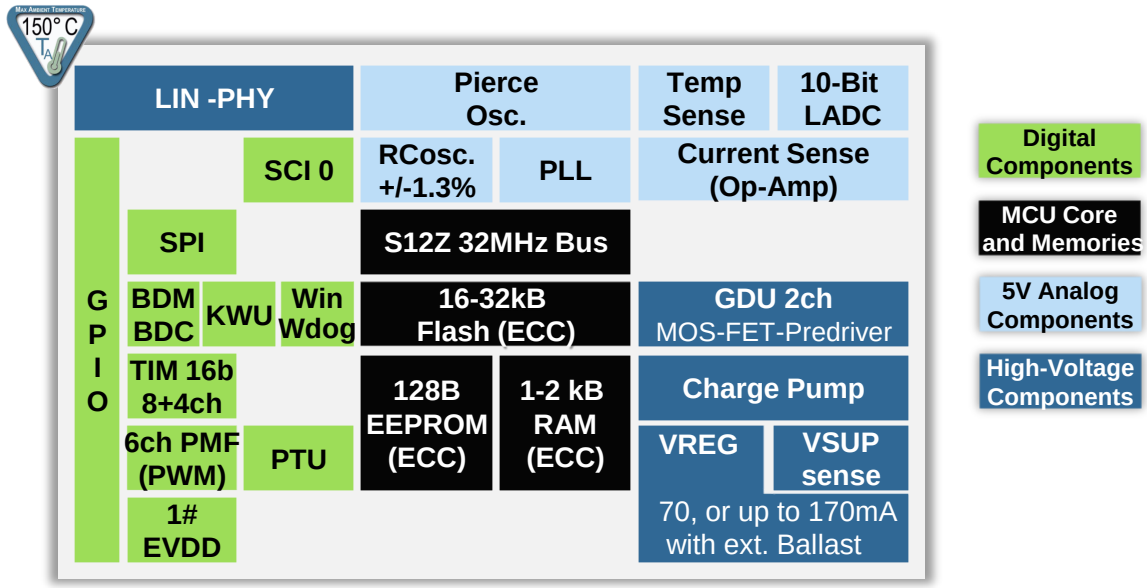
Options:

- Package: 48-LQFP; (64 LQFP tbd)
- Memory: 48 … 64kB Flash
- Temperature: V / M / W



MagniV Family Overview - S12ZVMA

LIN based Integrated half-Bridge driver



Key Features:

- S12Z CPU @ 32MHz bus speed
- VREG + 5V/70mA; nominal 6-18V; extended (with degradation) down to 3.5V with boost option (fuelpump)
- HV-PHY / LIN PHY, LIN2.1 / 2.2 / J2602 compliant; HV-PHY allows control of directly through 12V PWM command (with error/tack response)
- 16/32kB Flash, 2kB RAM, 128B EEPROM
- Half-Bridge Gate Pre-Driver for 2-NMOS control (1xLS, 1xHS; Gate Charge 50-80nC)
- Integrated Bootstrap Diode (to charge the external bootstrap capacitor)

Applications:

- DC-motors (unidirectional) such as pumps, fans
- Electromechanic actuators (eg. Valves)
- Any kind of automotive load that remotely needs to get switched by a FET (via a LIN or PWM-signal) like horn, aux. Heating, lighting, smart junction box, ...

Options:

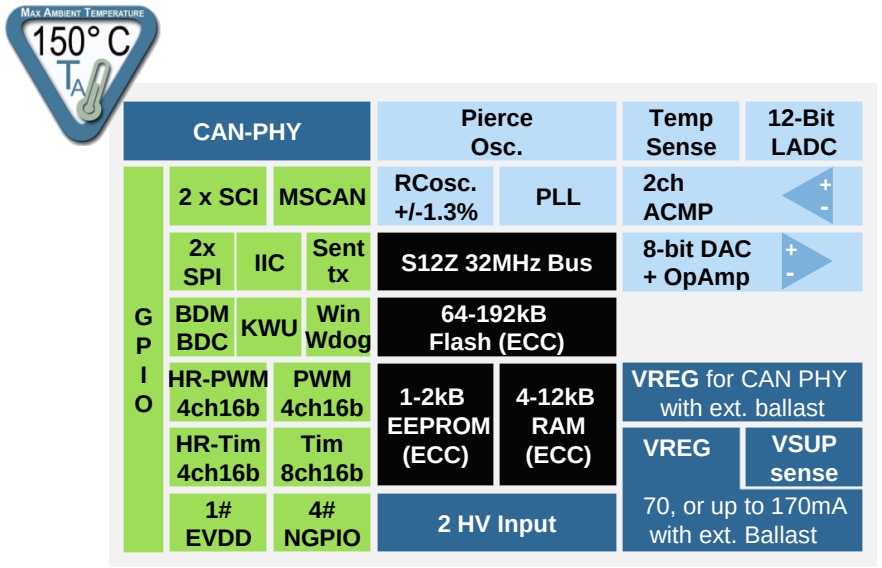
- Package: 32-LQFP; 48-LQFP
- Memory: 16 … 32kB Flash
- Temperature: V, M, W
- LIN: with LIN-PHY or with HV-PWM-interface

MagniV Family Overview - S12ZVC

Integrated CAN Nodes

Key Features:

- S12Z core (32 MHz)
- On chip CAN PHY:
  - CAN-supply requires ext. Ballast Transistor
  - Dominant Txd timeout
  - OEM emission limits achieved WITHOUT Choke (up to 500kbps)
- 12V VREG (device + ext comp)
  - 70mA total, 170mA with ext. Ballast
- High Voltage Input (HVI)
  - internal tied ADC for 12V analog measurements
- Specific features for sensor applications:
  - list-based 12-Bit ADC (LADC)
  - 16ns resolution Timer / PWM
  - 2x Analog Comparator with 8Bit DAC
  - SENT



Family Options:

- Flexible Memory Options: 64 kB to 128 kB Flash version
- 48-LQFP or 64-LQFP-EP Packaging
- C / V / M / W Temperature options (**up to 150°C Ta**)
- Fully featured (S12ZVCAx) or reduced featureset S12ZVCx)

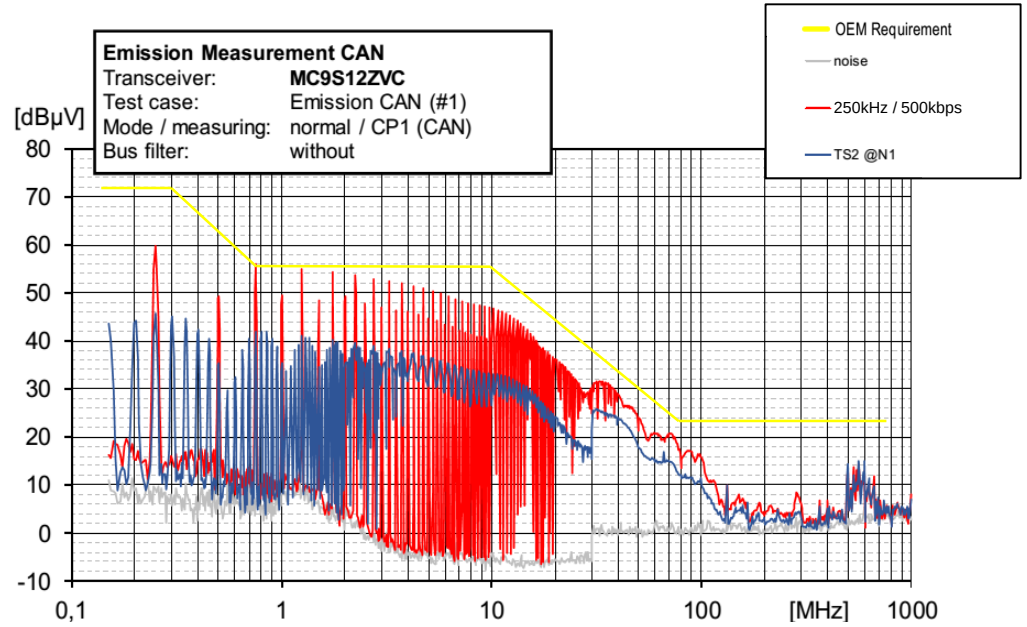
S12ZVC: OEM Emission Limits Achieved without Choke (up to 500kbps)

Operation without Common Mode Choke

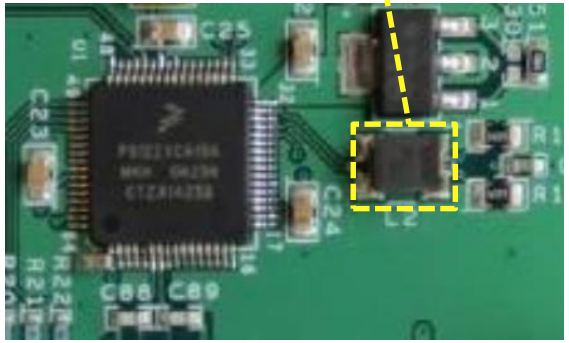
Saving:
~$0.20 BOM cost
~40mm² PCB area

Configuration without bus filter

Test case 1:
Emission CAN
- normal mode

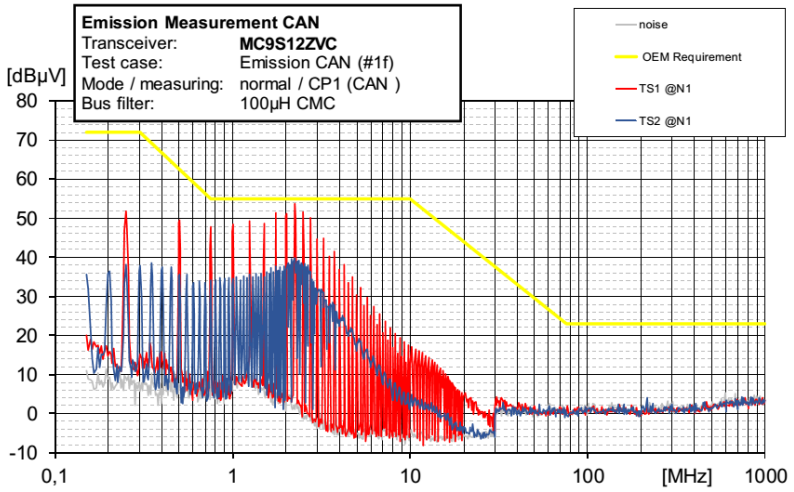


Operation With Common Mode Choke



Configuration with 100 µH CMC

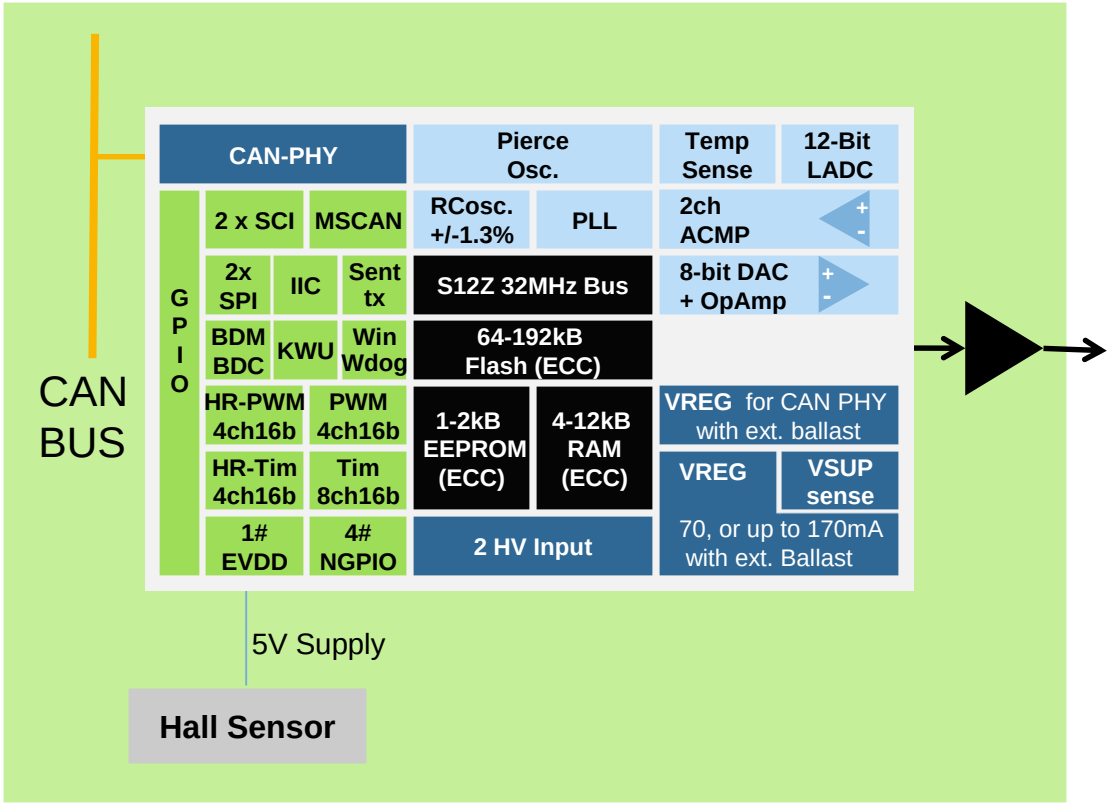
Test case 1f:
Emission CAN
- normal mode



S12ZVC for Seatbelt Pretensioner

S12ZVC Benefits:

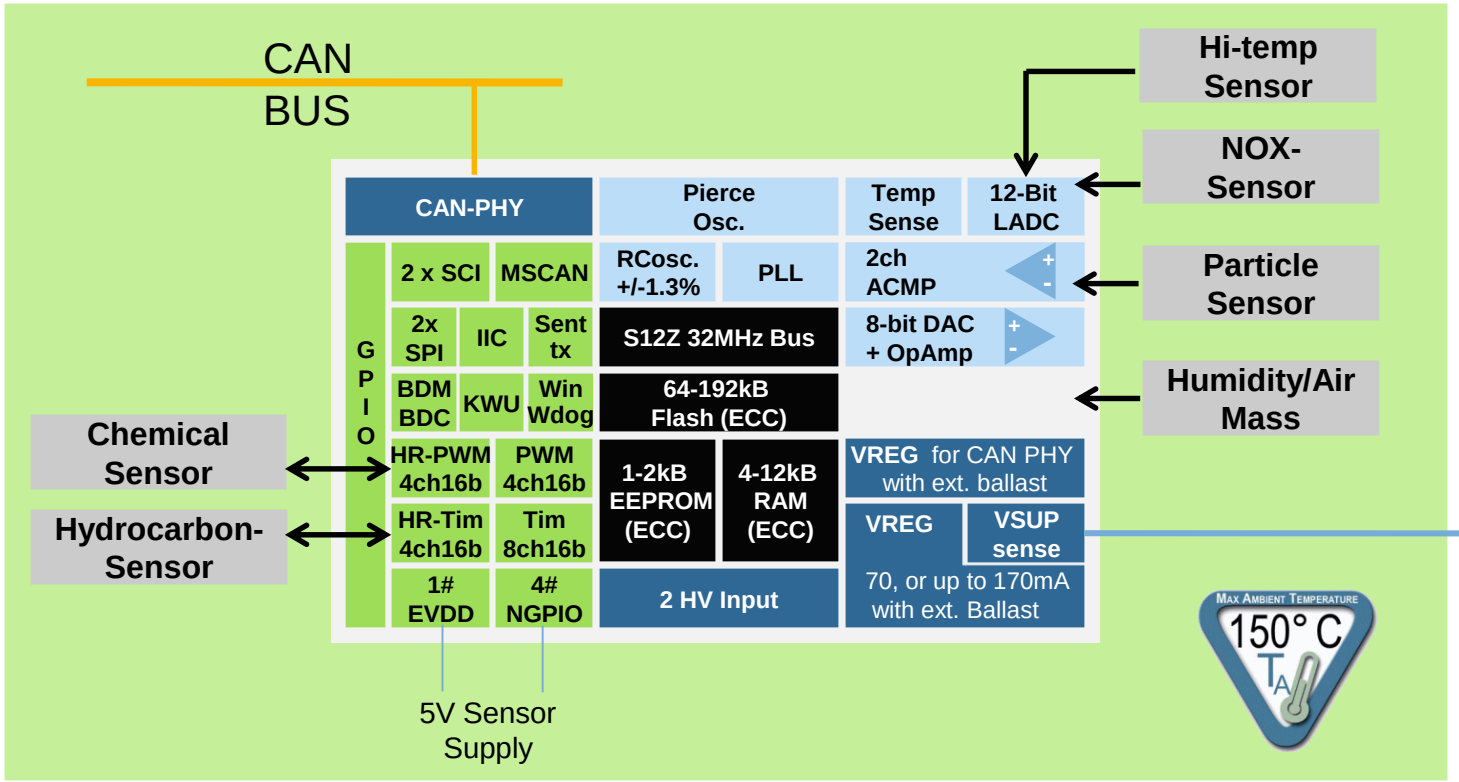
- CAN-based
- Limited PCB-space
- ASIL-requirements



S12ZVC for Powertrain Sensors

S12ZVC Benefits:

- Limited PCB-space
- ASIL-requirements
- High resolution timers and DMA enabled LADC
- On-chip analog comparator and DAC
- EVDD 5 V switchable sensor supply

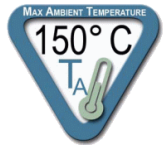


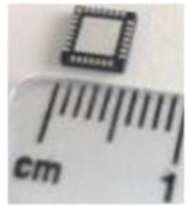
MagniV Family Overview - S12ZVL

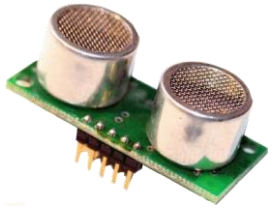
Integrated LIN Nodes

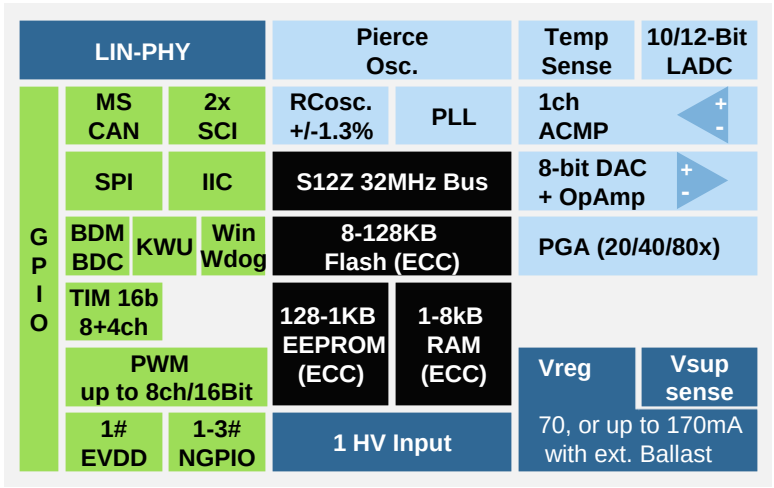
Key Features:

- S12Z core (32 MHz)
- 12V VREG (device + ext comp)
  - 70mA total (170mA with ext. Ballast)
- LIN-PHY, LIN2.x / J2602 compliant
- MS-CAN digital interface (48K+ only)
  - CAN – LIN gateway
- On chip RC Oscillator
  - +/- 1.3% over full temp range
  - No need for ext Xtal
- High Voltage Input (HVI)
  - internal tied ADC for 12V analog measurements
- Evdd 5V/20mA (switchable output overcurrent protected)
- List-based 10-Bit ADC (LADC)
- Optional S12ZVL**A** : enhanced analog
  - 12-Bit LADC, PGA, Analog Comparator, and DAC
- 1-3x N-GPIO (25 mA sink capability









Digital Components | 5V Analogue Components | MCU Core and Memories | High-Voltage Components

Family Options:

- Flexible Memory Options: 8 kB to 128 kB Flash version
- Optional Analog Enhancement (S12ZVL**A**64/96/128) with 12 Bit ADC, ACMP, DAC & PGA
- 32-LQFP , 48-LQFP or 32QFN Packaging
- C / V / M /W Temperature options (up to 150°C Ta)

S12ZVL Target Applications

LIN Sensors

Product Function

- Connect sensors to LIN-Network (with signal pre-conditioning)

Market Requirements

- LIN-PHY, 12V-Vreg, MCU
- Small form factor (QFN)
- ADC, SPI

LIN Switch Panels

Product Function

- Read multiple switch-positions and feed into LIN-network

Market Requirements

- LIN-PHY, 12V-Vreg, MCU
- Multiple GPIOs
- ADC

LIN Actuator

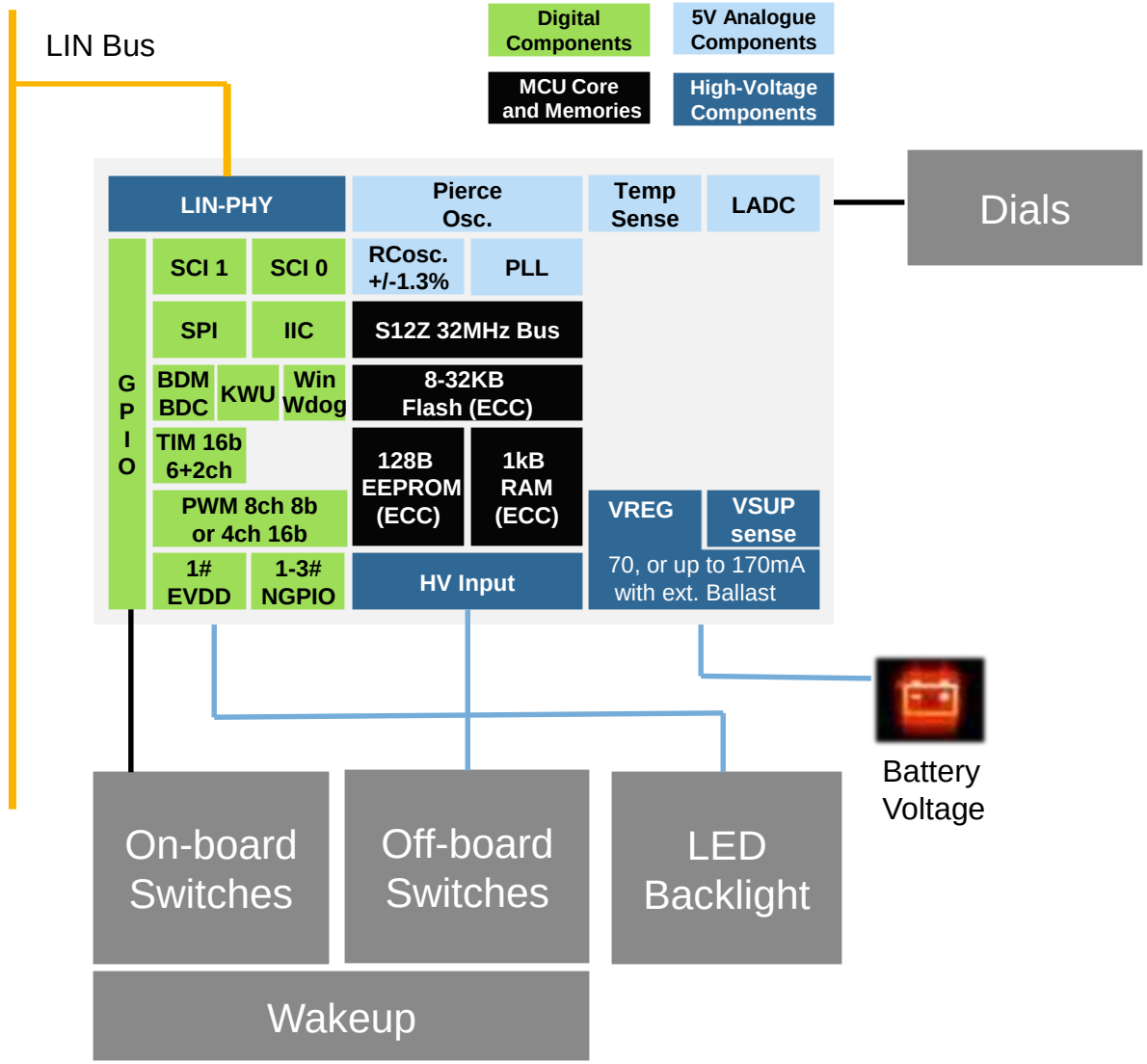
Product Function

- Convert LIN-command into an activity (eg driving LEDs)

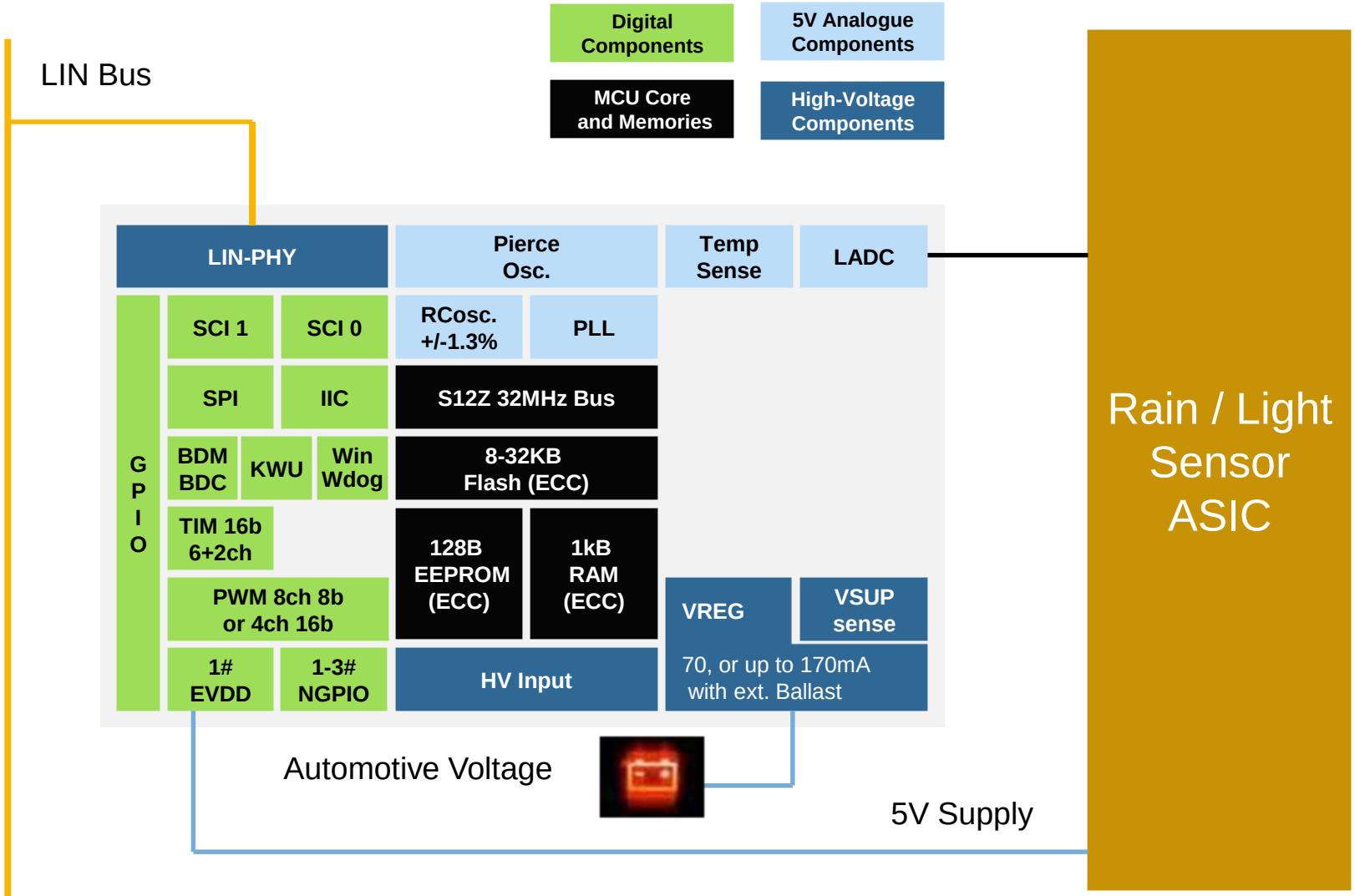
Market Requirements

- LIN-PHY, 12V-Vreg, MCU
- Drivers (3x25mA drive strength in case of RGB-LED)
- ADC

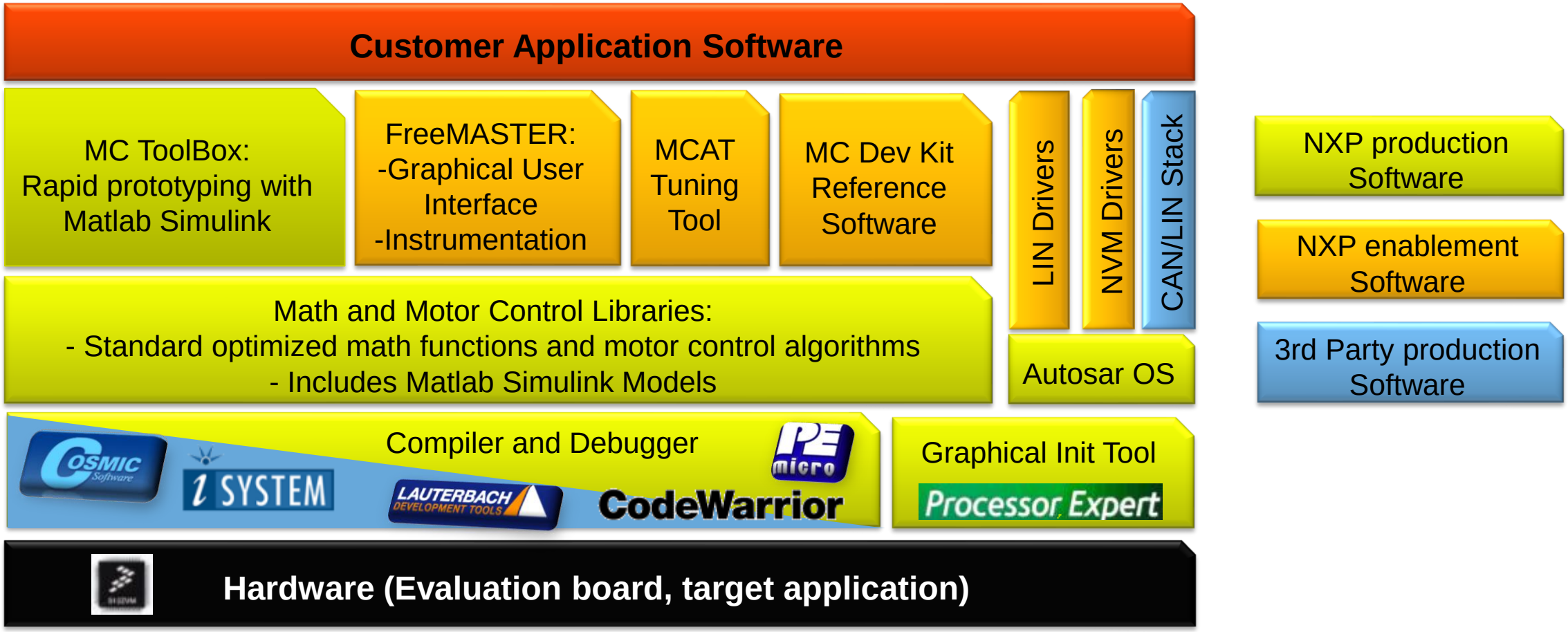
S12ZVL for Switch Panel Applications



S12ZVL for Sensor Applications



MagniV Family Overview - The Complete Solution



MagniV Family Overview Summary

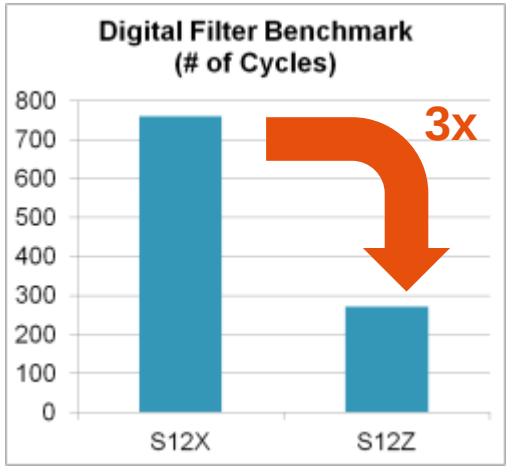
- MagniV Most Common Success Factors:
  - High analog **integration** for reduced PCB size and system cost
  - Wide **scalability** supporting platform design
  - **Ease of use** by having key active components integrated
  - **Pre-certification** for EMI/EMC for approval at major OEM's reducing Tier1's risk
  - **Market Leadership** in integrated solutions
  - Ahead of competition on several turnkey-solutions for **Faster Time to market**
  - **Grade0 support** not only for motor control
  - Strong **knowledge & support** on Software and Hardware enabling customers Motor Control Applications
  - Supporting **Safety & Security** Standards

S12Z CORE INTRODUCTION

S12Z Performance Benefits

Improved Performance for Motor Control

- 100 MHz CPU @ 50 MHz bus speed
- Harvard architecture accelerates data handling



- Improved standard math instructions (32bit MAC)
- Fractional math instructions added
- Advanced Register set optimized to achieve less memory access (improves current consumption)

Improved Software Friendliness

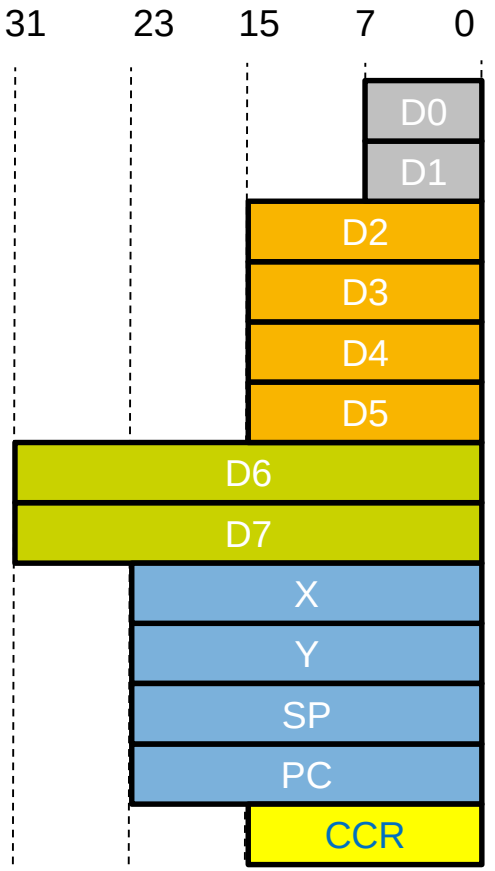
- 24-bit linear address map to ease software development and porting
- Instructions/addressing optimized for C programming
- Added 8- and 32-bit registers allow further compiler code size optimization

S12Z… really a 16-bit MCU?

24-bit address bus maps up to 16MB (no paging needed!)

- Multiple length registers / data paths:
  - 32-Bit data paths, ALU, Data registers
  - 24-bit address bus, Stack Pointer, Program Counter and X/Y Index registers
  - It has a 16-bit I/O data path
  - 16-bit is its “int” native data type
  - Handles 8-Bit data and indices better than S12X
- Benefits:
  - 24-bit address = 16MB vs. 64KB of a typical 16-bit address bus
  - Multiple length registers = less RAM load/store accesses

Expanded programmer’s model



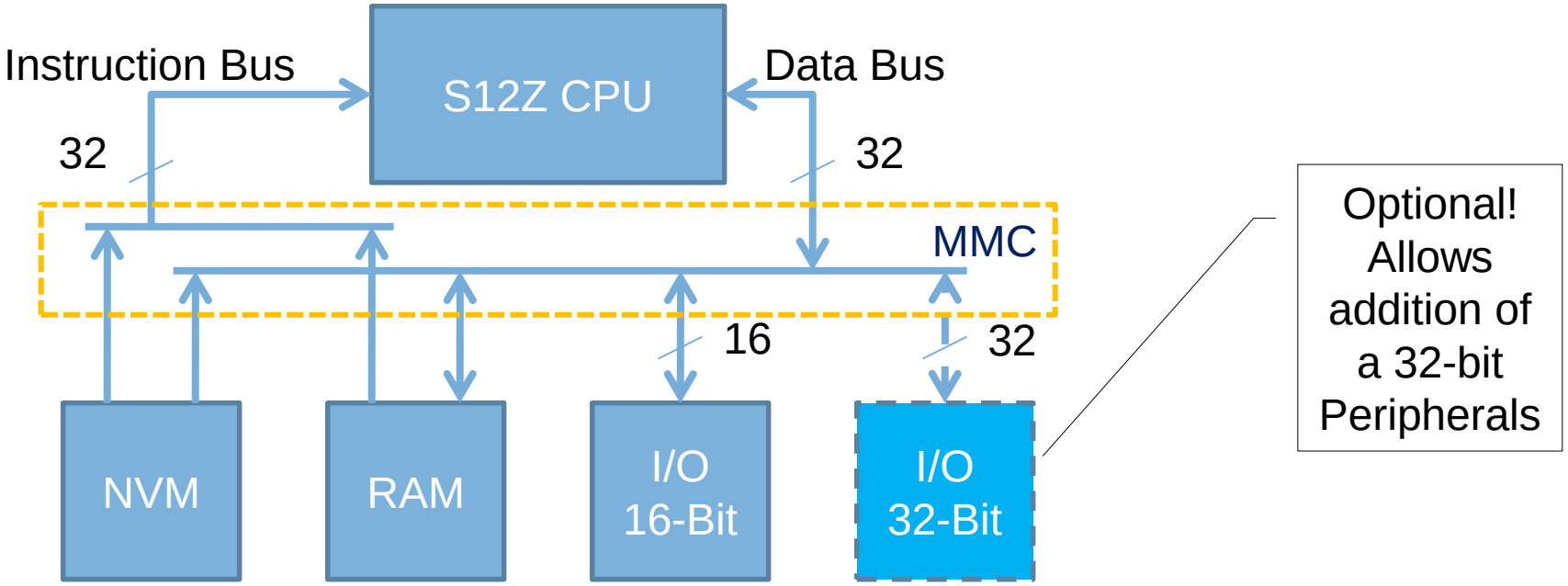
S12Z CPU Enhancements

Instructions and Addressing optimized for C-programming

- Harvard Architecture – Parallel data & code accesses
- CPU operates at 100MHz
- Fractional Math support
- Instructions/addressing optimized for C programming
- Register set optimized to reduce code size and memory access

Attribute	S12Z		S12XE	
Shifter	**32**-Bit multi-bit	1 cycle	16-bit single-bit	2 cycles
Multiplier	**32*32** 16*16	2.5 cycles 1 cycle	-- 16*16	 1 cycle
Divider	32 = **32/32**	18.5 cycles	32 = 32/16	11 cycles
MAC	32 += **32*32**	3.5 cycles	32 += 16*16	13 cycles
Fractional math support	**Yes**		No	
Bus speed	50MHz		50MHz	

S12Z core - Platform

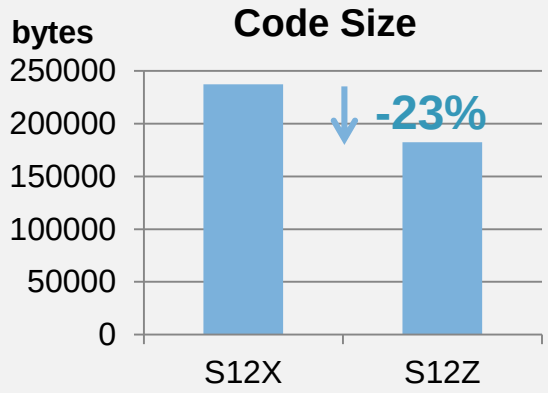


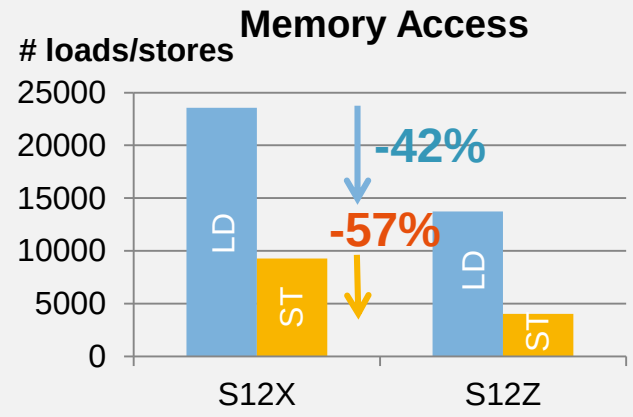
- CPU operates at 100MHz (All performance numbers for 180nm!)
- NVM works with 1 Wait-state => effective 20ns accesses
- RAM bus can load and store w/ 100MHz
- I/O busses are working w/ 50MHz to reduce power consumption and die area

S12Z Benchmarks Results

- S12Z typically saves ~20% code size versus S12X
- S12Z typically uses ~30% less memory accesses than S12X which saves power

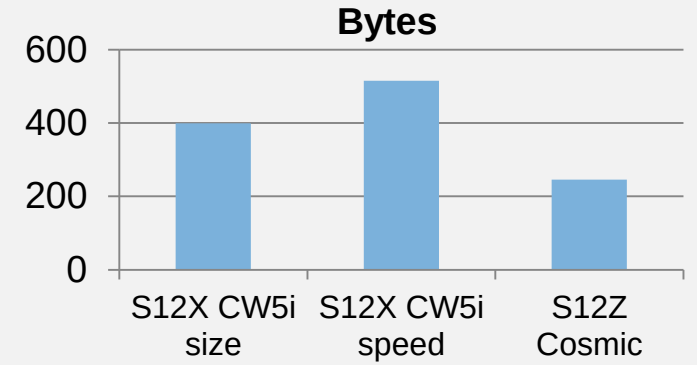
Large Application Code Example:

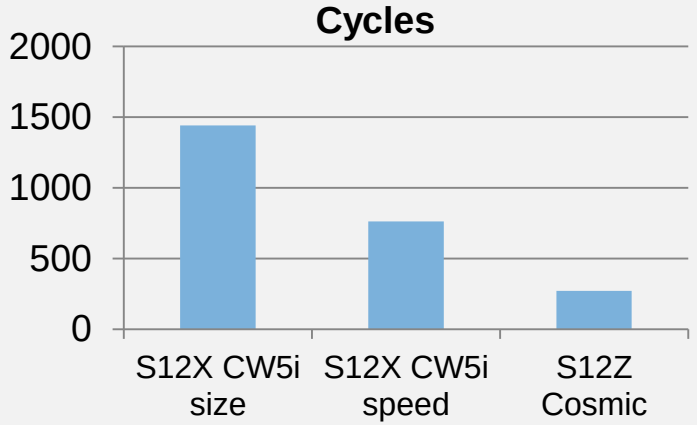




Digital Filter:

S12Z is faster and denser than any optimization option of S12X





S12Z – Cost aspects

- Code size typically 20% smaller than S12X
  ⇒ Smaller NVM size needed
  ⇒ Less NVM accesses => lower current consumption

- Register set optimized
  ⇒ Less RAM loads & Store required (ca. -30% vs. S12X)
  ⇒ lower current consumption

- Overall >2x better MIPS/mW expected

- Faster code development time due to simpler memory model and better “C-friendliness” of the instruction set

PERIPHERAL INTRODUCTION (SELECTED)

Peripheral Introduction - Overview

High-Voltage Components

- **VREG for tot. supply:**
  - 70mA w/o ext comp. or
  - 170mA with ext. ballast
- **LIN-PHY** | **CAN-PHY**
- **V-BAT SENSE** | **V-SUP SENSE**
- **HVI** (12V-input with ADC)
- **LS-drivers** | **HS-drivers**
- **Charge Pump**
- **4-6ch MOSFET Predriver (50-100nC)**

Digital Components

- **MS-CAN** | **SCI**
- **SPI** | **IIC**
- **GPIO** | **PGPIO 20mA** | **NGPIO 25mA**
- **BDM/BDC**
- **Key Wakeups** | **Win Wdog**
- **RTC**
- **Timer** 16Bit (25-64MHz) | **PWM** 8/16Bit (25-50MHz)
- **Motorcontrol PWM With Fault protection**
- **Programmable Trigger Unit**
- **Sound Generator**
- **Segment LCD (4x40)**
- **Stepper Motor Driver with SSD**

MCU Core and Memories

- **S12- or S12Z-CPU 25/32/50MHz bus**
- **Flash (ECC) 8kB – 128kB**
- **EEPROM (ECC) 128B – 4kB**
- **RAM (ECC) 512B - 8kB**

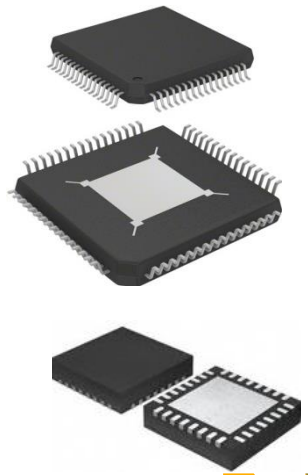
5V Analogue Components

- **ADC** 10-12Bit resolution 1-2 S/H-units Up to 16ch total
- **Temp Sense**
- **Current Sense** (2 x Op-Amp)
- **Pierce Osc.**
- **RCosc. +/-1.3%** | **PLL**

Packaging

- **LQFP:** 32/48/64/100/144-pin
- **LQFP-EP:** 48/64-pin 

- **QFN:** 32-pin (5x5mm)



Peripheral Introduction – CPMU

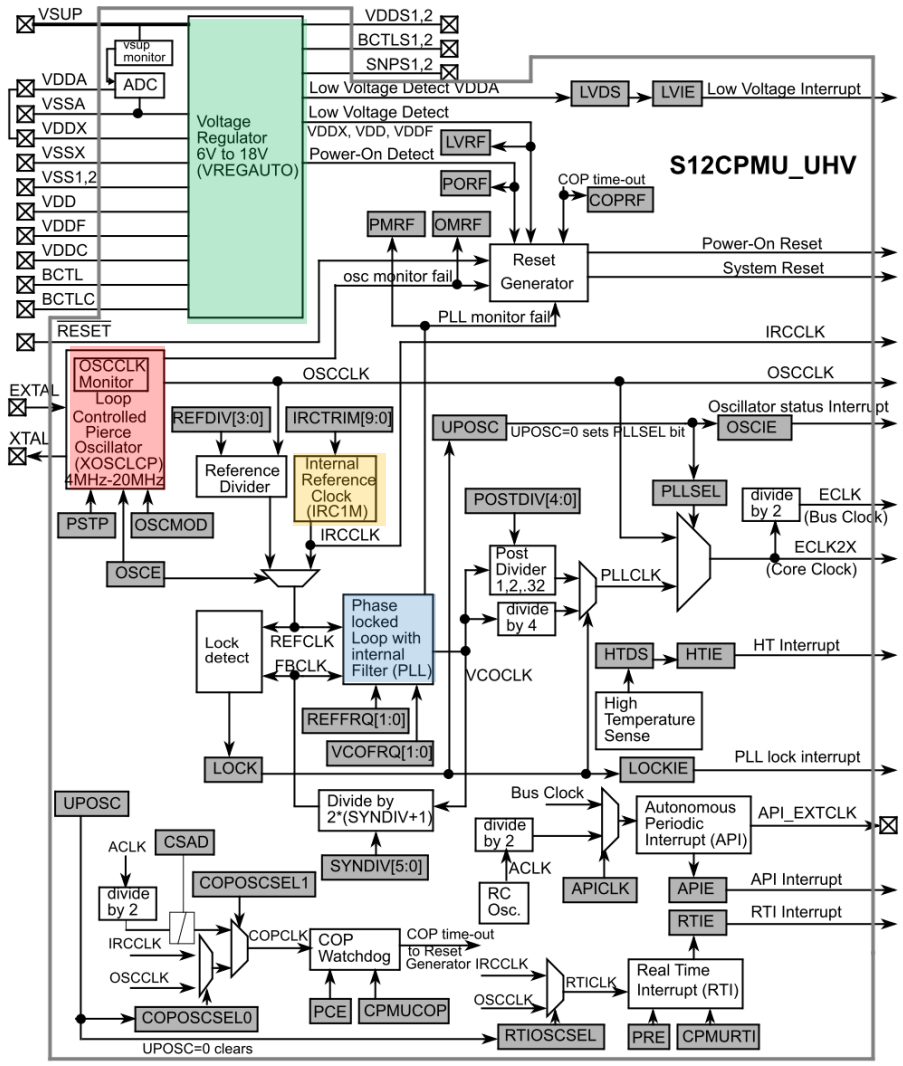


Figure 8-1. Block diagram of S12CPMU_UHV_V10_V6

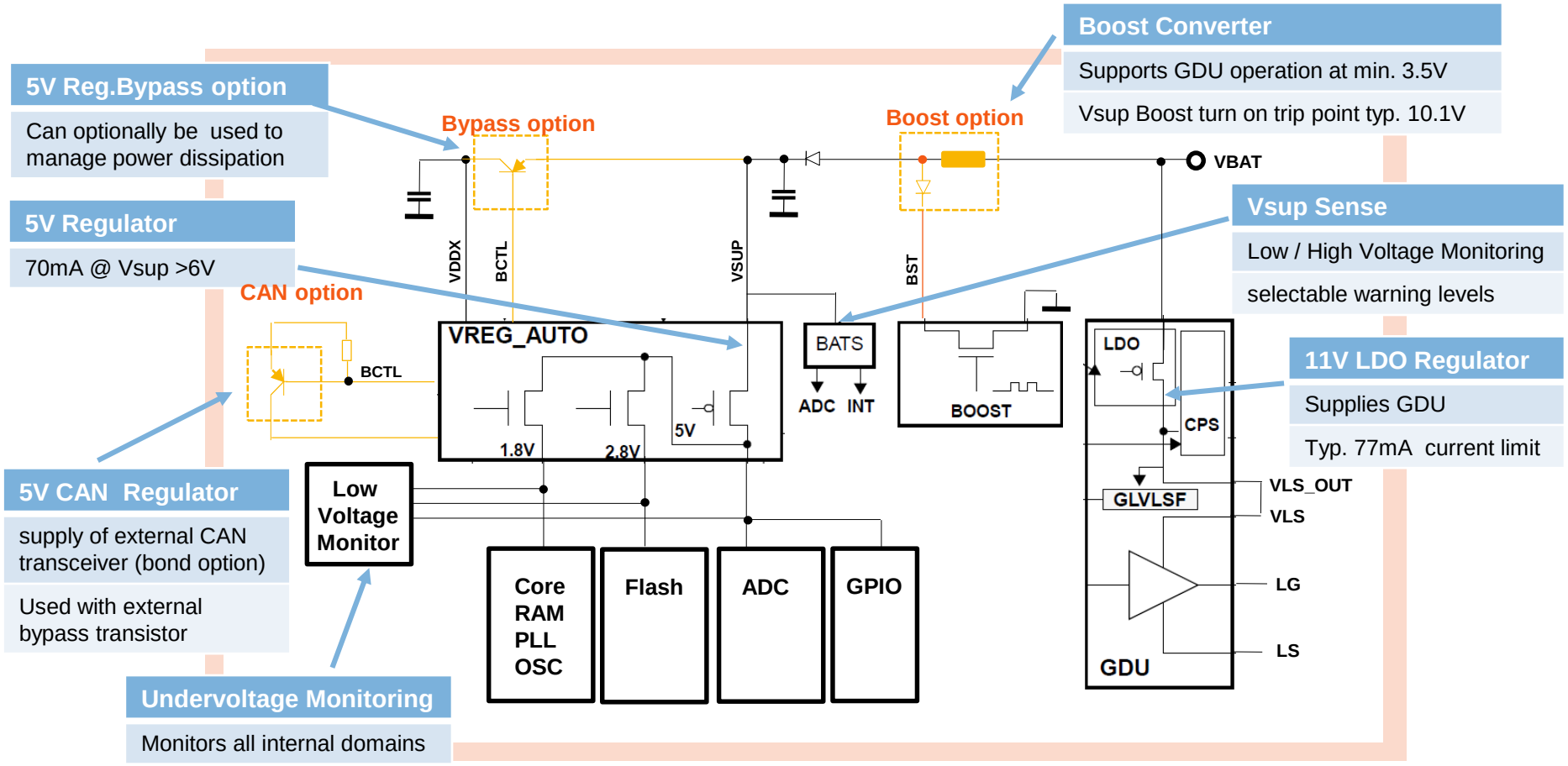
XOSCLCP | VREGAUTO | PLL | IRC1M

- The Pierce oscillator (XOSCLCP) provides a robust, low-noise and low-power external clock source. It is designed for optimal start-up margin with typical crystal oscillators
- The Voltage regulator (VREGAUTO) operates from the range 6V to 18V. It provides all the required chip internal voltages and voltage monitors
- The Phase Locked Loop (PLL) provides a highly accurate frequency multiplier with internal filter
- The Internal Reference Clock (IRC1M) provides a 1MHz internal clock.

Peripheral Introduction – Power Domain

S12ZVM for example

Flexible Boost & Bypass Option



Peripheral Introduction – Power Domain

S12ZVM for example

Boost Converter

Can optional ly be enabled

Vsup Boost turn on trip point typ. 10.1V

Vsup Sense

Monitors Vsup

5V Regulator

70mA @ Vsup >6V

1.8V Core Regulator

Follows 5V regulator

5V CAN Regulator

For supply of external CAN Transceiver (bond option with LIN/LGND pins)

Used with external bypass transistor

2.8V Flash Regulator

Follows 5V regulator

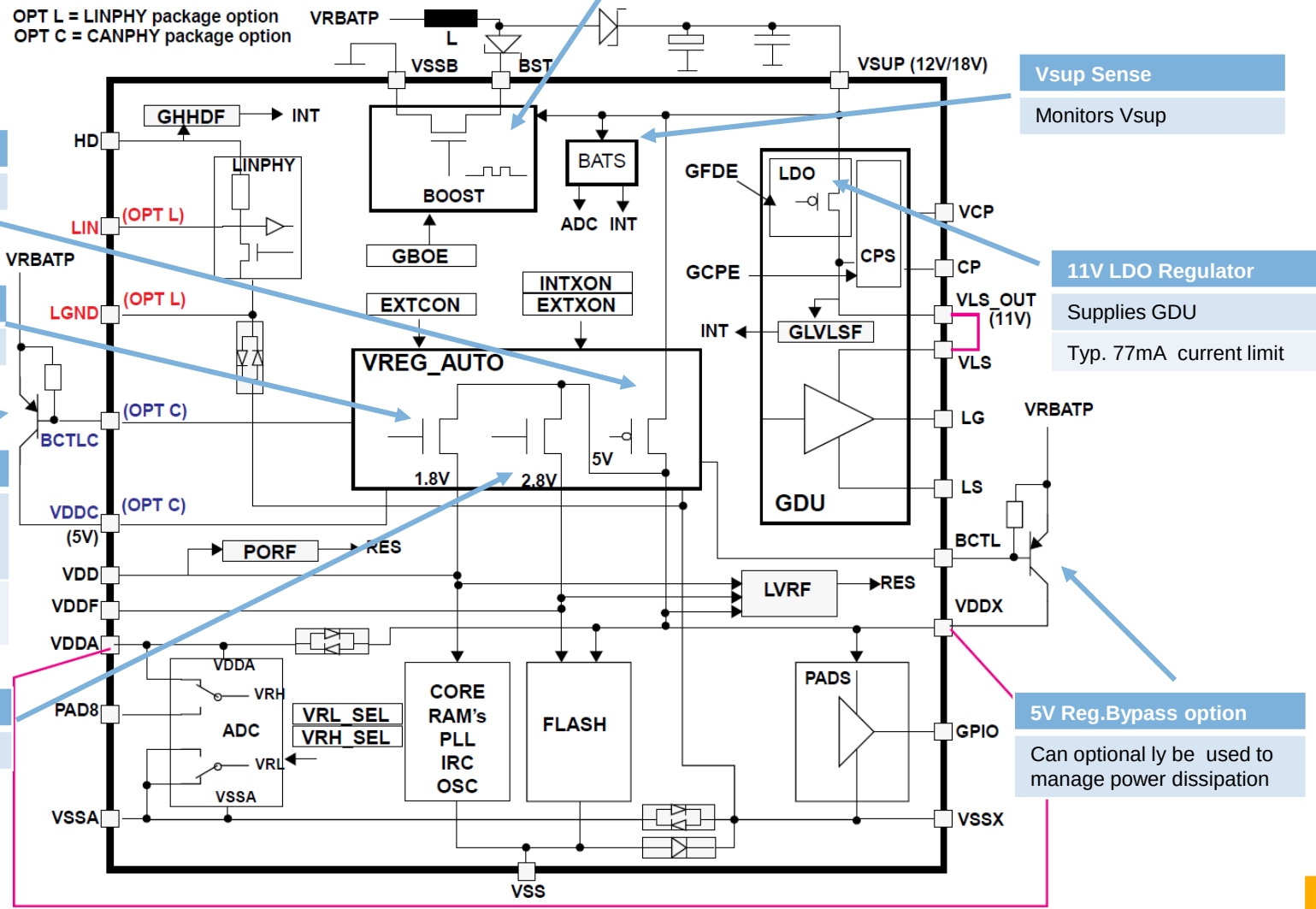
11V LDO Regulator

Supplies GDU

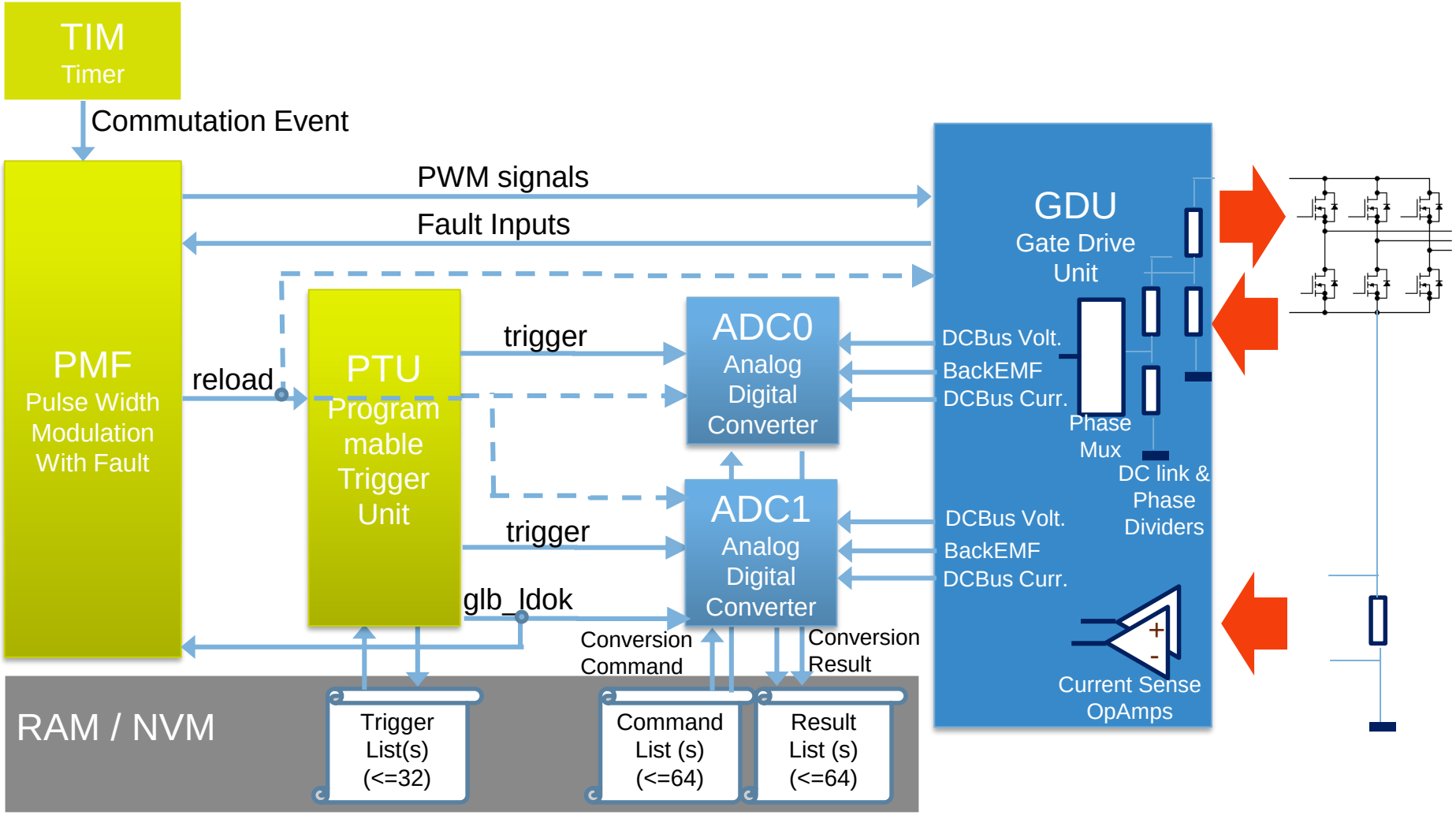
Typ. 77mA current limit

5V Reg.Bypass option

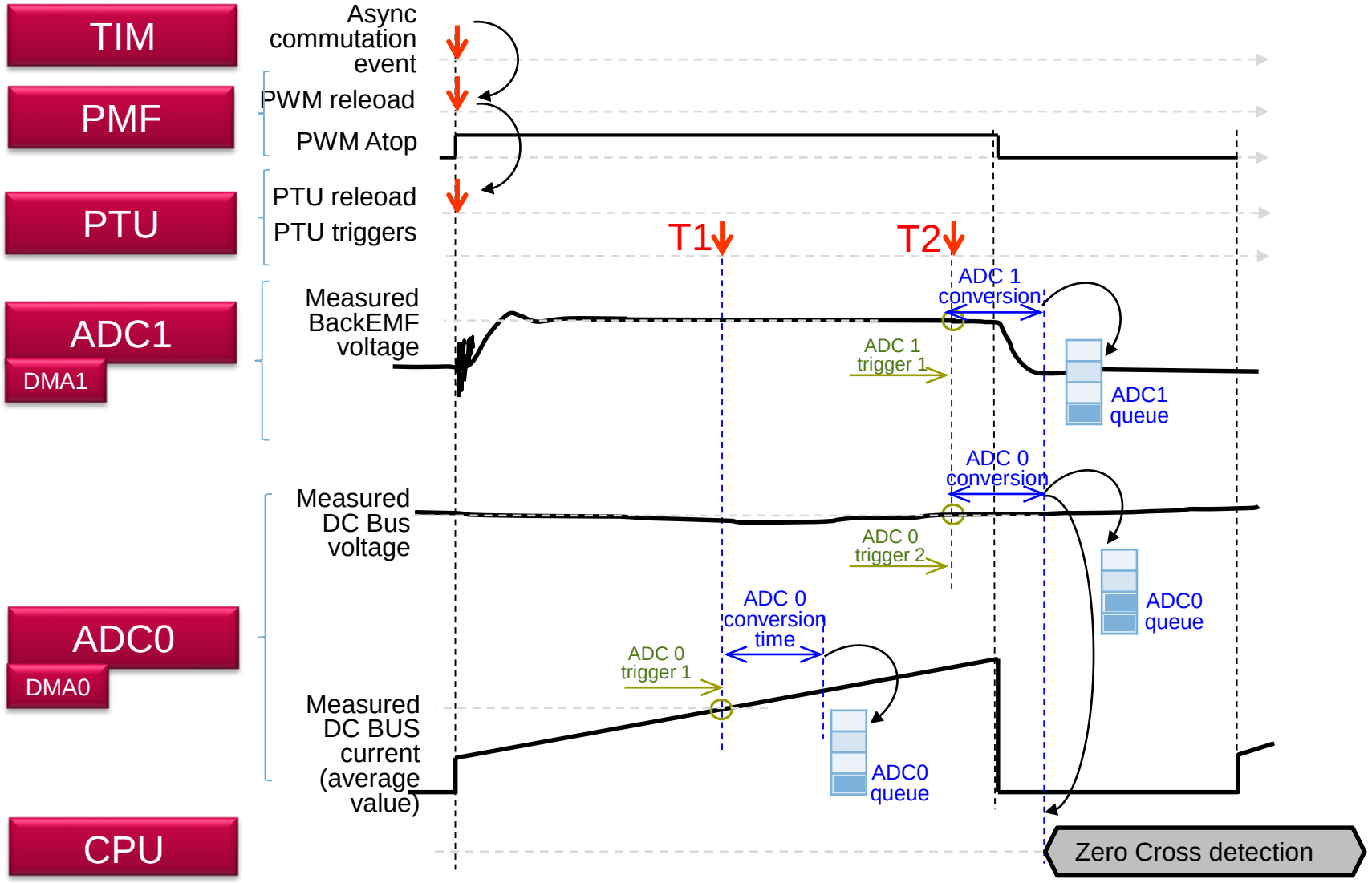
Can optional ly be used to manage power dissipation



Motor Control Loop Implementation

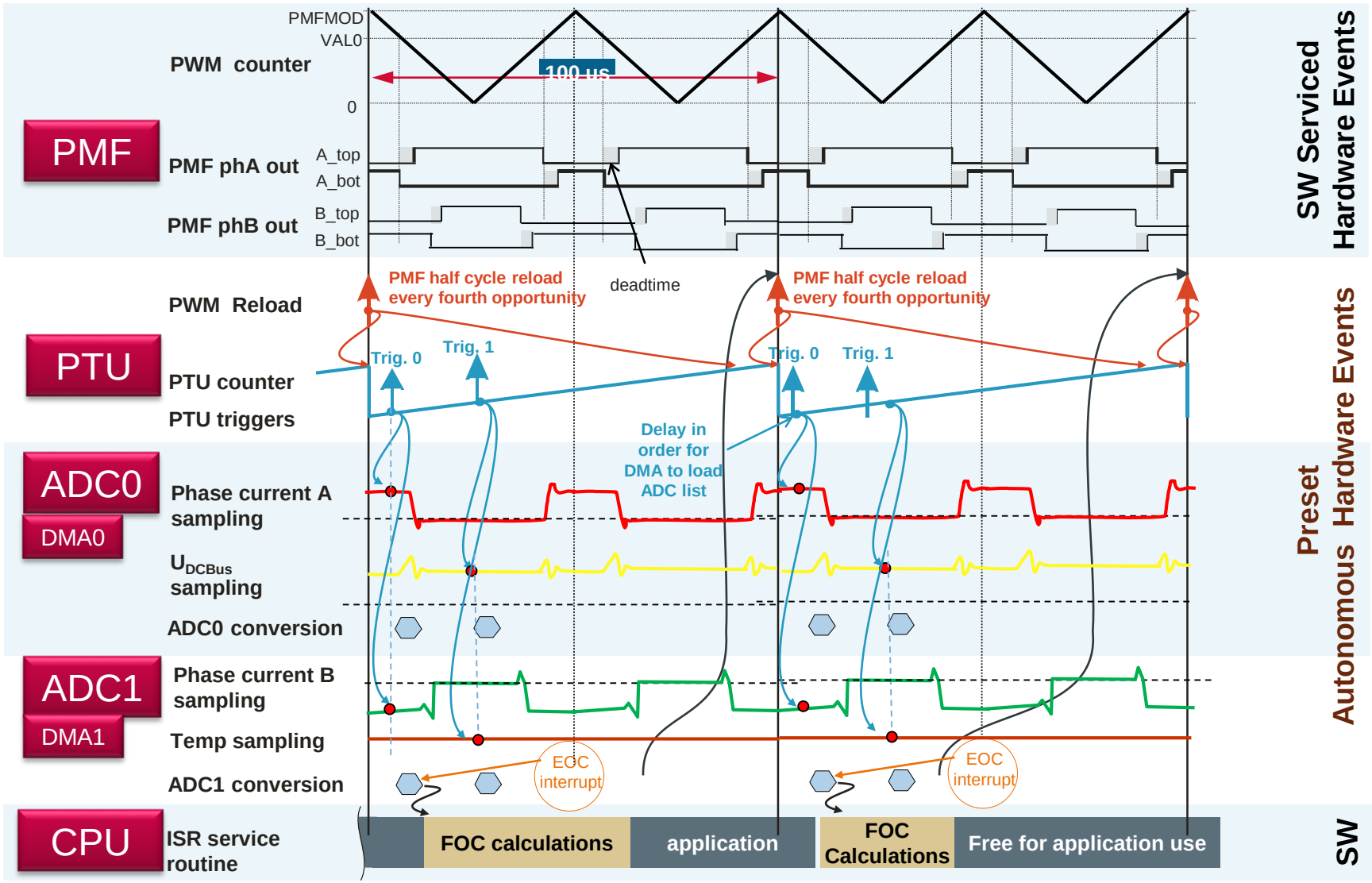


Fully automatic control loop



Autonomous PMSM Application Timing

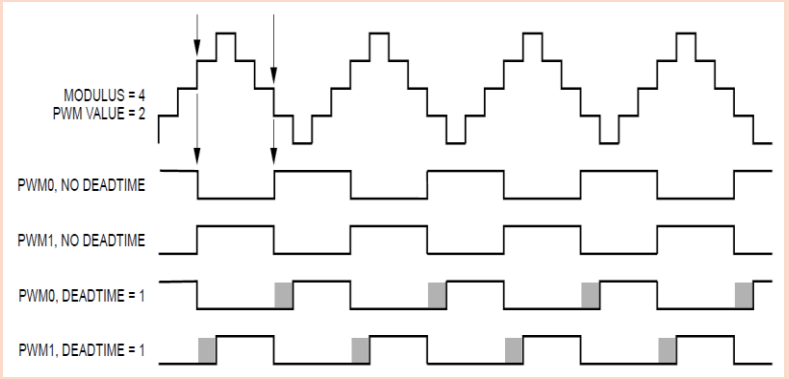
Two shunts current sensing



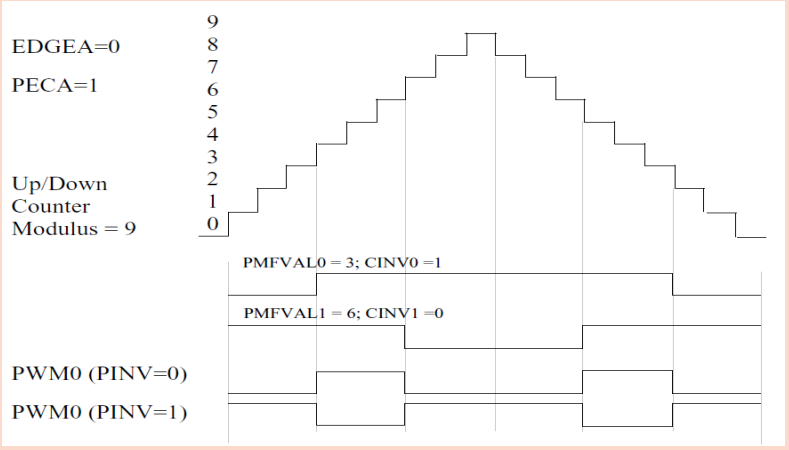
Pulse Width Modulator Module (PMF)

- **6 PWM channels, 3 independent counters**
  - Up to 6 independent channels or 3 complementary pairs
- **Based on core clock (max. 100MHz)**
- **Complementary operation:**
  - Dead time insertion
  - Top and Bottom pulse width correction
  - Double switching
  - Separate top and bottom polarity control
- **Edge- or center-aligned PWM signals**
- **Integral reload rates from 1 to 16**
- **6-step BLDC commutation support, with optional link to TIM Output Compare**
- **Individual software-controlled PWM outputs**
- **Programmable fault protection**

Complementary Mode
with / without dead time insertion



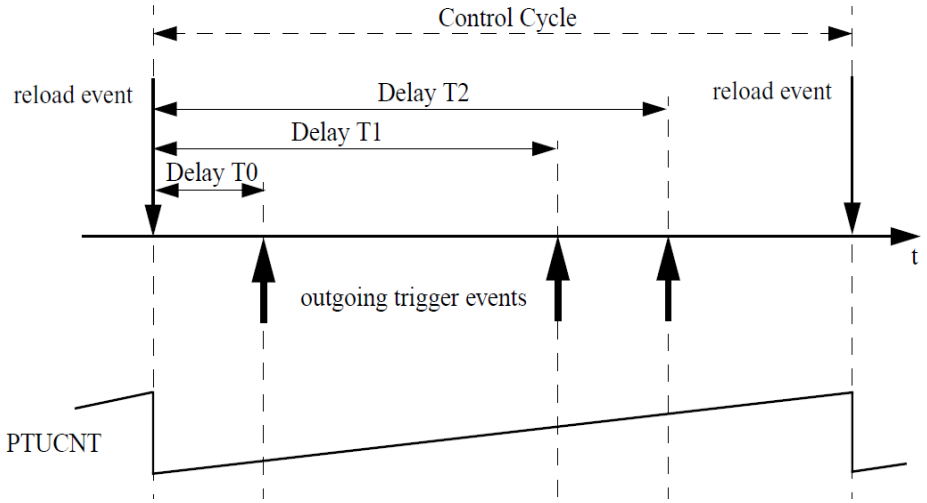
Double-Switching Mode
for single shunt system

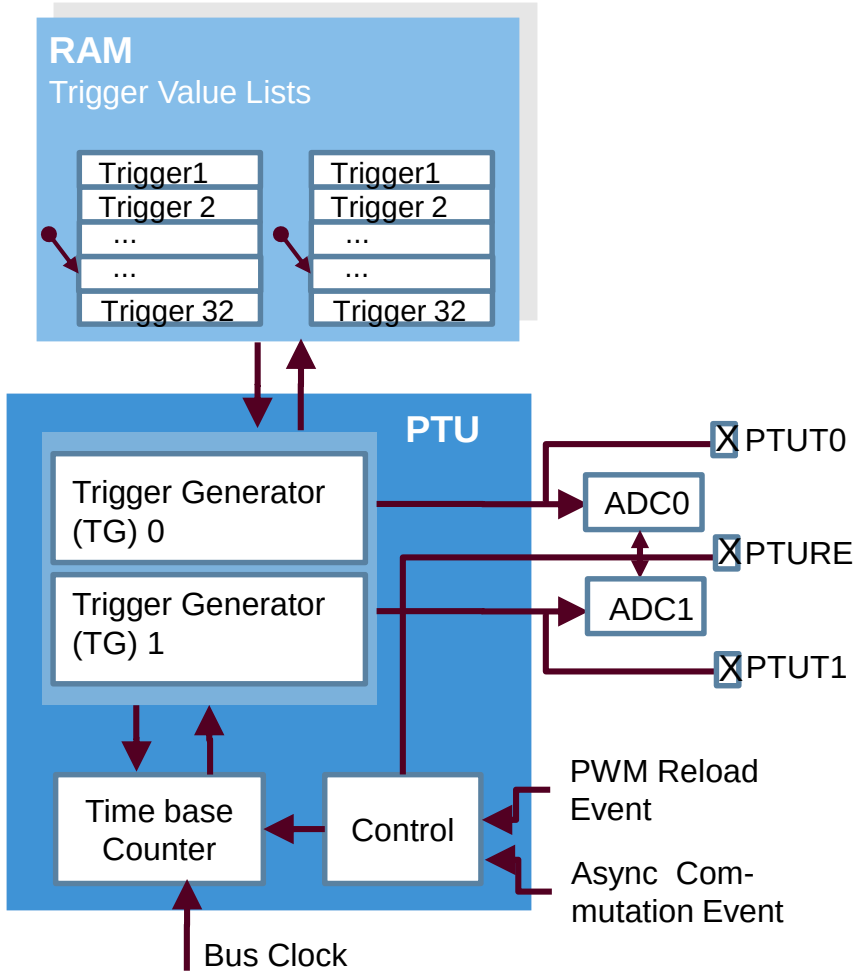


Programmable Trigger Unit (PTU)

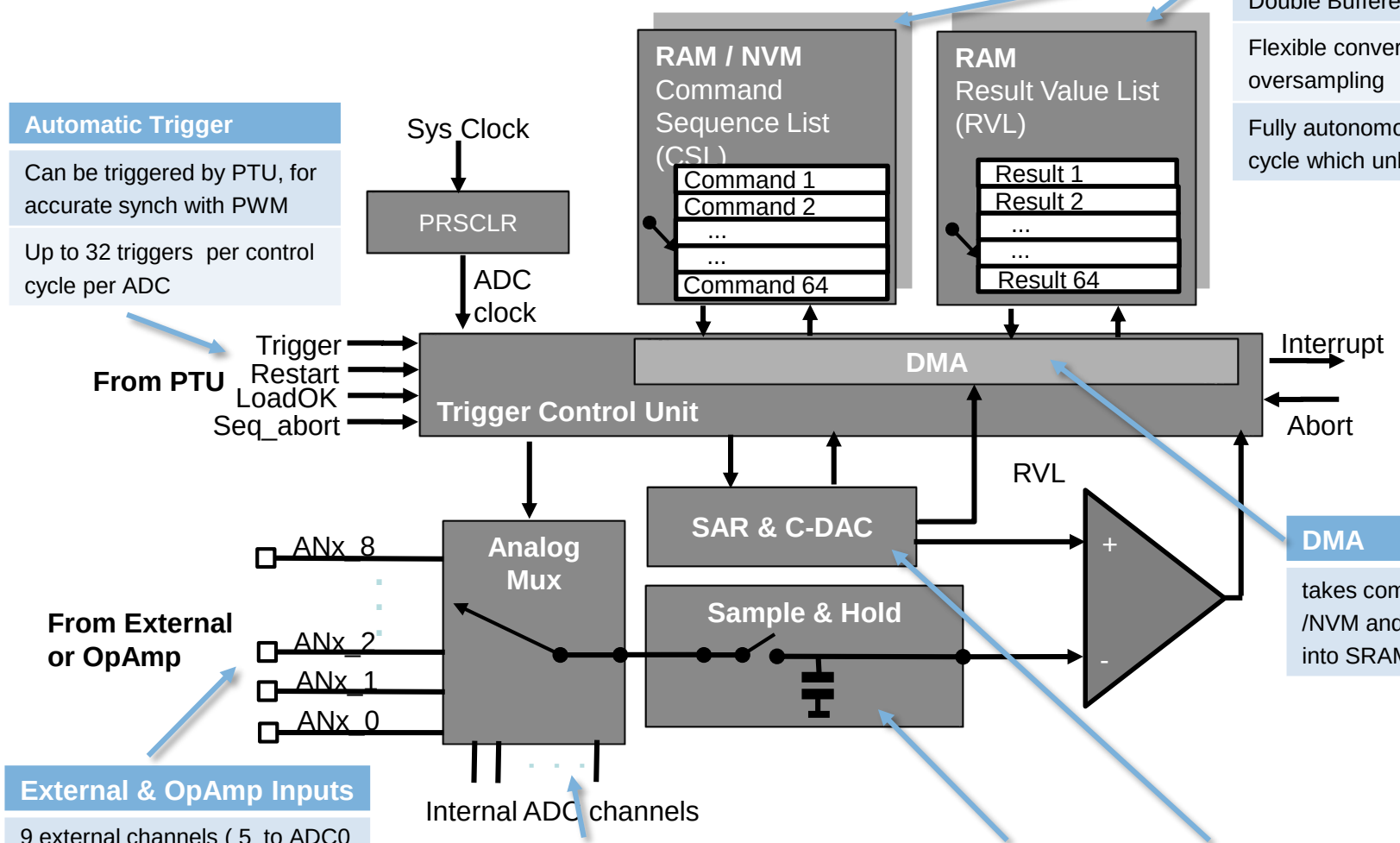
Completely avoids CPU involvement to trigger ADC during the control cycle

- One 16-bit counter as time base
- Two independent trigger generators (TG)
- Up to 32 trigger events per trigger generator
- Trigger Value List stored in system memory
- Double buffered list, so that CPU can load new values in the background
- Software generated “Reload” & trigger event
- synchronized with PMF and ADC to guarantee coherent update of all control loop modules





Peripheral Introduction – ADC



Automatic Trigger

Can be triggered by PTU, for accurate synch with PWM

Up to 32 triggers per control cycle per ADC

Command and Result List

Double Buffered

Flexible conversion sequence and oversampling

Fully autonomous motor control cycle which unloads CPU

DMA

takes commands from SRAM /NVM and stores results back into SRAM

External & OpAmp Inputs

9 external channels (5 to ADC0 and 4 to ADC1)

OpAmp Output shared with ADC external channel

Monitoring Internal Signals

DC Link, Phaase voltages, Vsup

Vreg & ADC Temp sensors

Bandgap voltage

Sample Time

Selectable : 480ns to 2.88µs

Conversion Time

1.8µs @ max. ADC clock for 12bit

Peripheral Introduction – ADC – Internal Channels

Internal Channels give access to following internal signals

ADC0

Channel Select						ADC Channel	Signal
0	0	1	0	0	0	Internal_0	ADC0 temperature sensor
0	0	1	0	0	1	Internal_1	VREG temperature sensor or Bandgap voltage
0	0	1	0	1	0	Internal_2	GDU phase multiplexer voltage
0	0	1	0	1	1	Internal_3	GDU DC link voltage monitor
0	0	1	1	0	0	Internal_4	BATS VSUP sense voltage

ADC1

Channel Select						ADC Channel	Signal
0	0	1	0	0	0	Internal_0	ADC1 temperature sensor
0	0	1	0	0	1	Internal_1	VREG temperature sensor or Bandgap voltage
0	0	1	0	1	0	Internal_2	GDU phase multiplexer voltage
0	0	1	0	1	1	Internal_3	GDU DC link voltage monitor

Peripheral Introduction – ADC – Conversion Modes

- Single channel conversion
- Multi channel conversion
  - Sequentially convert flexible selectable order of channels
- Continuous conversion on a single channel
- Continuous conversion on multiple channels
- Oversampling of a single channel
- Oversampling of multiple channel
  - Order and channel selection flexible

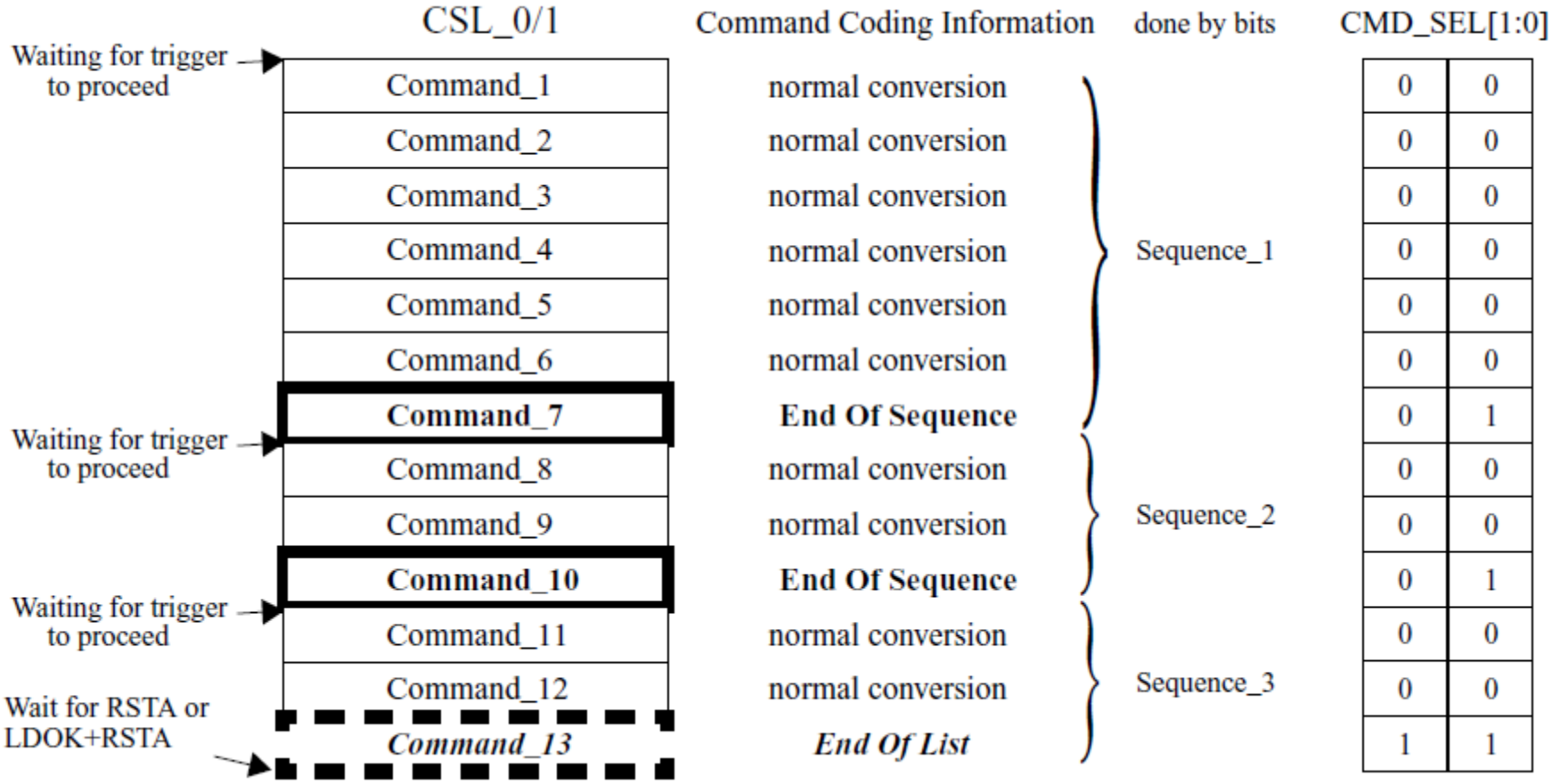
Trigger Mode

Restart event starts 1st conversion
Restart Event **IS** a trigger event

Restart Mode

Fully time controlled conversion
Restart Event **IS NOT** a trigger event

Peripheral Introduction – ADC – Command Sequence List

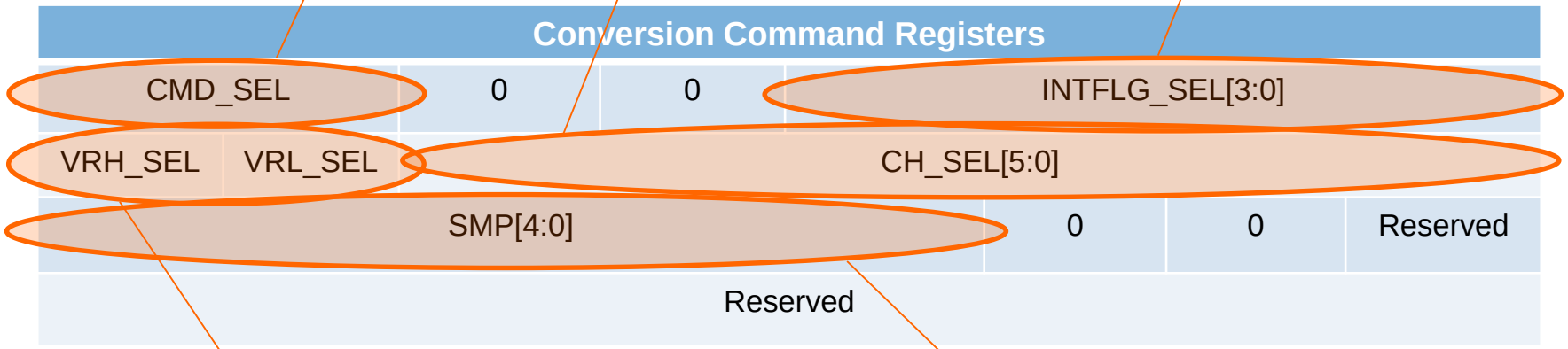


Peripheral Introduction – ADC – ADC Conversion Command

Conversion Command Type:
- Normal conversion
- End of sequence
- End of List

Conversion Interrupt Flag Select:
- which Int Flag gets set at end of conversion

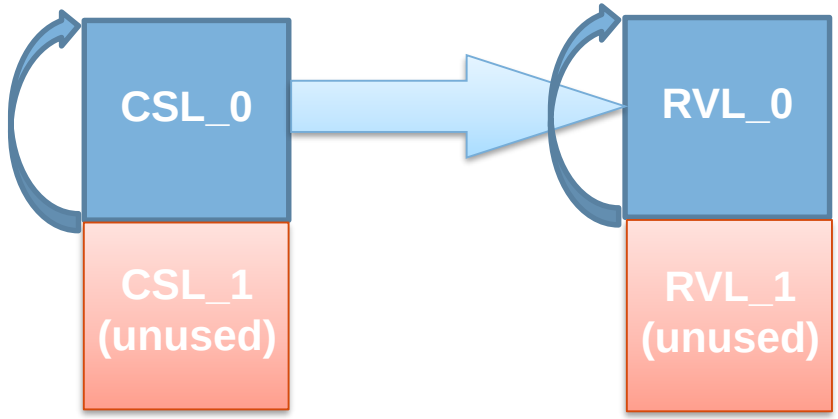
Conversion Input Channel Select:
- Select input channel for this conversion



Select Reference High / Low:
- VRH_SEL = 0 = VRH_0 Selected = PAD8 (default)
  VRH_SEL = 1 = VRH_1 Selected = VDDA
- VRL_SEL = 0 = VRL_0 Selected = VSSA
  VRH_SEL = 1 = VRL_1 Selected = VSSA
  VRL_1 recommended (low noise) = non-default

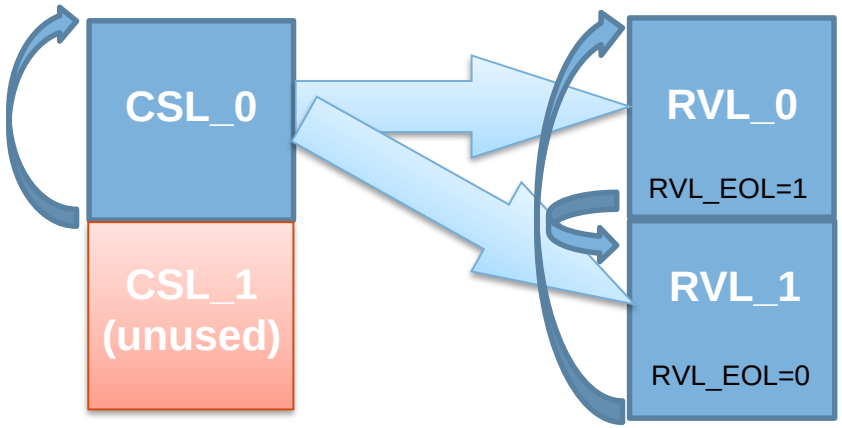
Sample Time Length:
- Select Sample Time in units of ADC clock cycles
- 4 to 24 ADC clock cycles selectable
  → fastest = 480ns @ 8.33MHz (up to 150°C Tj)
  @ 50MHz bus
  → fastest = 640ns @ 6.25MHz (up to 175°C Tj)
  @ 50MHz bus

ADC – Command Sequence List & Result Value List



CSL single buffer mode - RVL single buffer mode

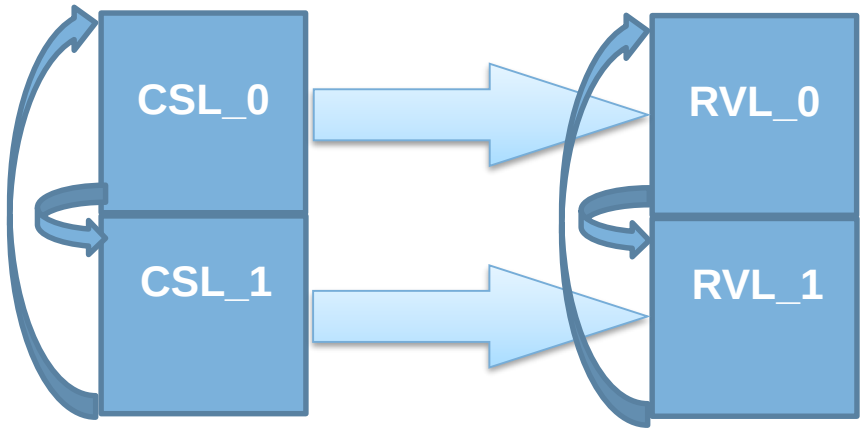
- default setting after reset
- after last command in list with type identifier End of list“ CSL and RVL index counters



CSL single buffer mode - RVL double buffer mode

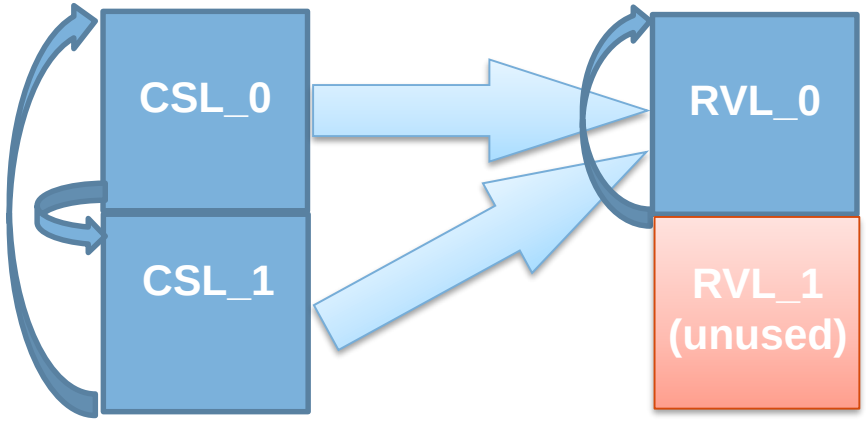
- increases latency time for CPU to read RVL buffers
- after last command in CSL or after CSL abort the RVL is switched
- first command result of new CSL cycle gets stored in new RVL
- RVL_EOL bit in ADCEOLRI register shows the last active RVL when “End Of List” command type was executed

ADC – Command Sequence List & Result Value List usage



CSL double buffer mode - RVL double buffer mode

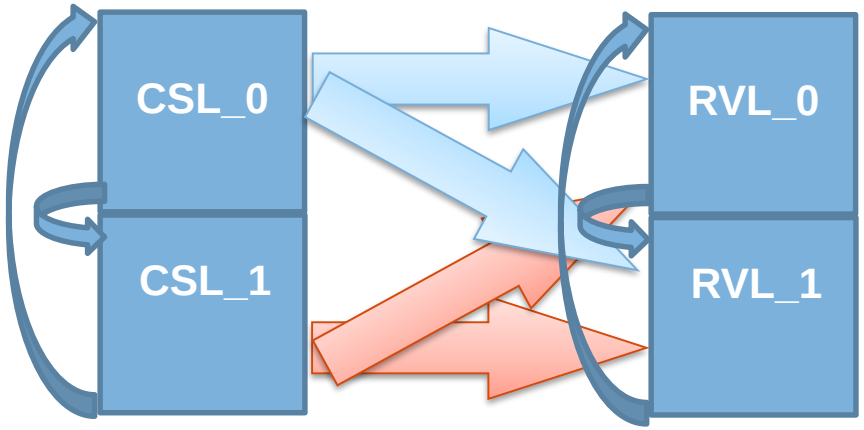
- can be used if the channel order or CSL length varies very frequently in an application.
- CSL and RVL switch after CSL end of list command reached and after assertion of LDOK+RSTA



CSL double buffer mode - RVL single buffer mode

- can be used if the channel order or CSL length varies very frequently in an application with different result SW handling
- CSL switchs after CSL end of list command reached and after assertion of LDOK+RSTA, while RVL index gets cleared

ADC – Command Sequence List & Result Value List usage



CSL double buffer mode - RVL double buffer mode

- at the end of a CSL end of list command the CSL is not always swapped (bit LDOK not always set with bit RSTA).
- The Result Value List is swapped whenever a CSL is finished or a CSL got aborted.

ADC – Conversion Flow Control

- The conversion flow is controlled by signals which are reflected in the ADC Conversion Flow Control Register ADCFLWCTL :
  - SEQA (Seq_Abort), TRIG(Trigger), RSTA(Restart), LDOK(LoadOK)

ADCFLWCTL Register

	7	6	5	4	3	2	1	0
R	SEQA	TRIG	RSTA	LDOK	0	0	0	0
W								
Reset	0	0	0	0	0	0	0	0

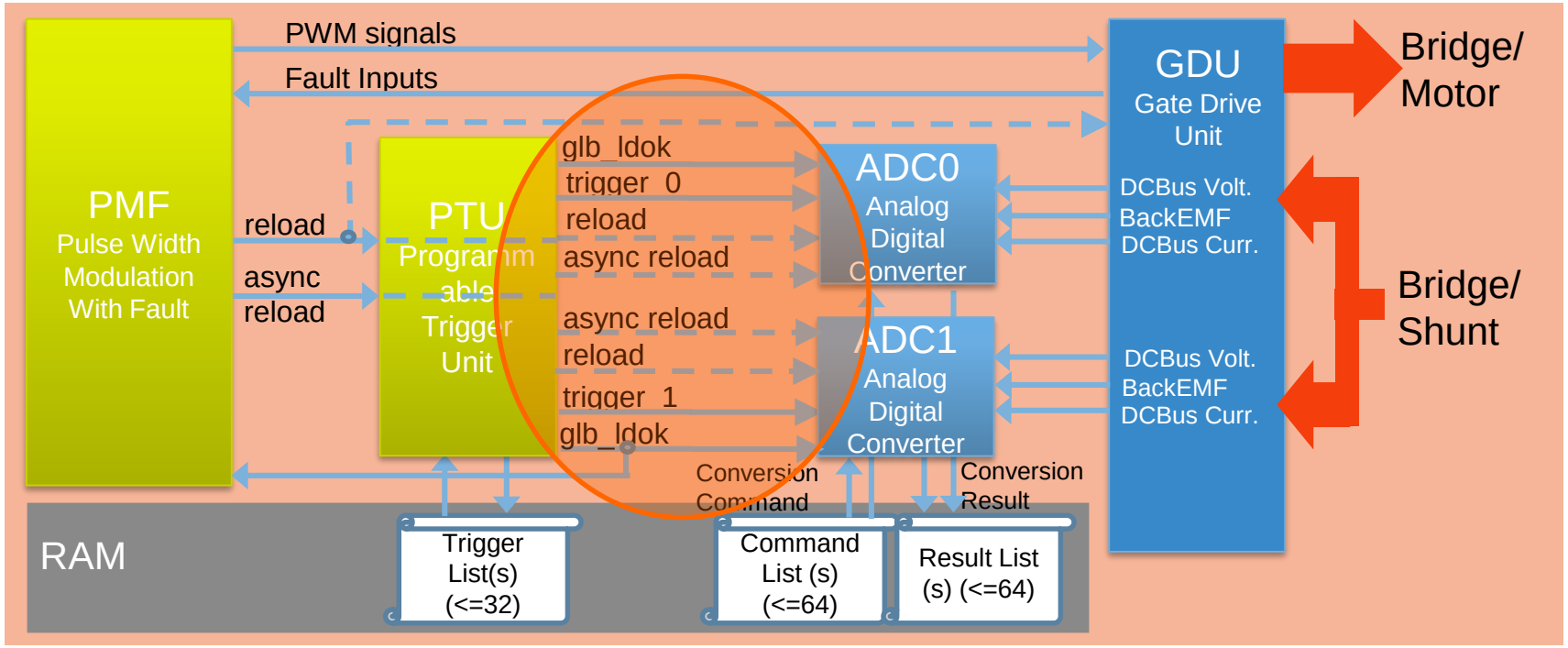
- They can be modified in two different ways:
  - Via Data-Bus accesses
  - Via Internal Interface Signals (Trigger, Restart, LoadOK and Seq_Abort)
  - This is selected by ACC_CFG bits in ADCCTRL0 Register

ADCCTL_0 Register

	15	14	13	12	11	10	9	8
R	ADC_EN	ADC_SR	FRZ_MOD	SWAI	ACC_CFG[1:0]		STR_SEQA	MOD_CFG
W								
Reset	0	0	0	0	0	0	0	0

ACC_CFG [1]	ACC_CFG [0]	Access Mode
0	0	No access path enabled
0	1	Single Access via Internal Interface
1	0	Single Access via Data Bus
1	1	Dual Access mode

ADC – Internal Conversion Flow Signals

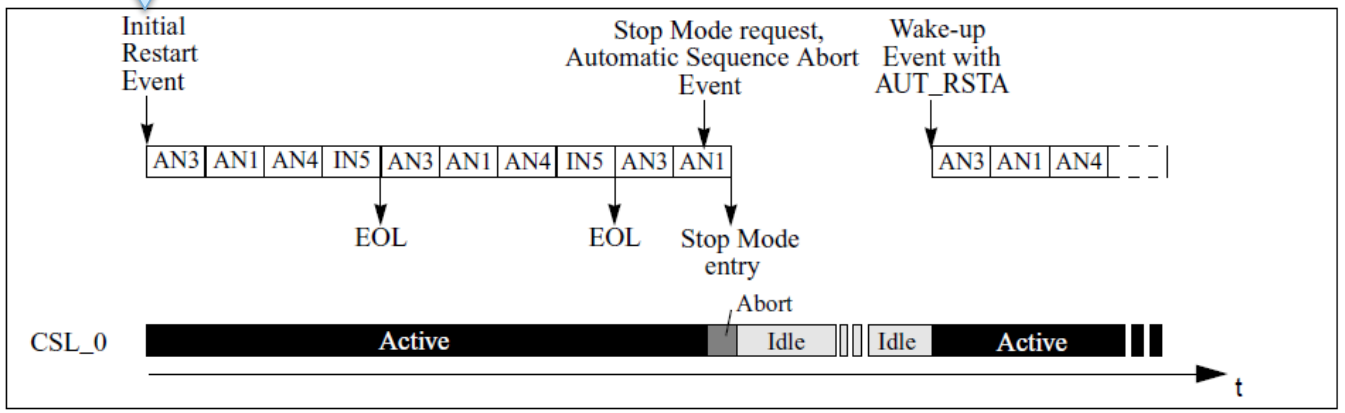


Device Level Event	TIM	PMF	PTU	ADC0	ADC1
commutation_event	OC0(1)	commutation_event	—	—	—
reload	—	reloada(2)	reload	Restart	Restart
async_reload	—	async_reload	async_reload	Seq_abort	Seq_abort
trigger_0	—	—	trigger_0	Trigger	—
trigger_1	—	—	trigger_1	—	Trigger
glb_ldok	—	glb_ldok	glb_ldok	LoadOK	LoadOK

1. TIM channel OC0 must be configured to toggle on both edges

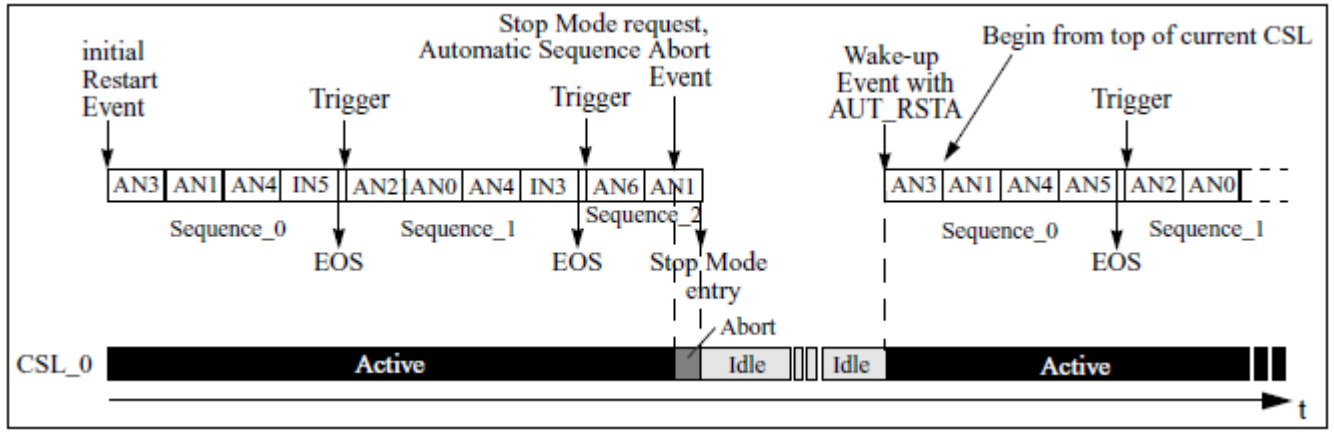
ADC – Conversion Flow Trigger Mode

Restart Event = Trigger for first coverstion sequence



Example 1:
Trigger Mode used for simple continuous conversion in single buffer mode

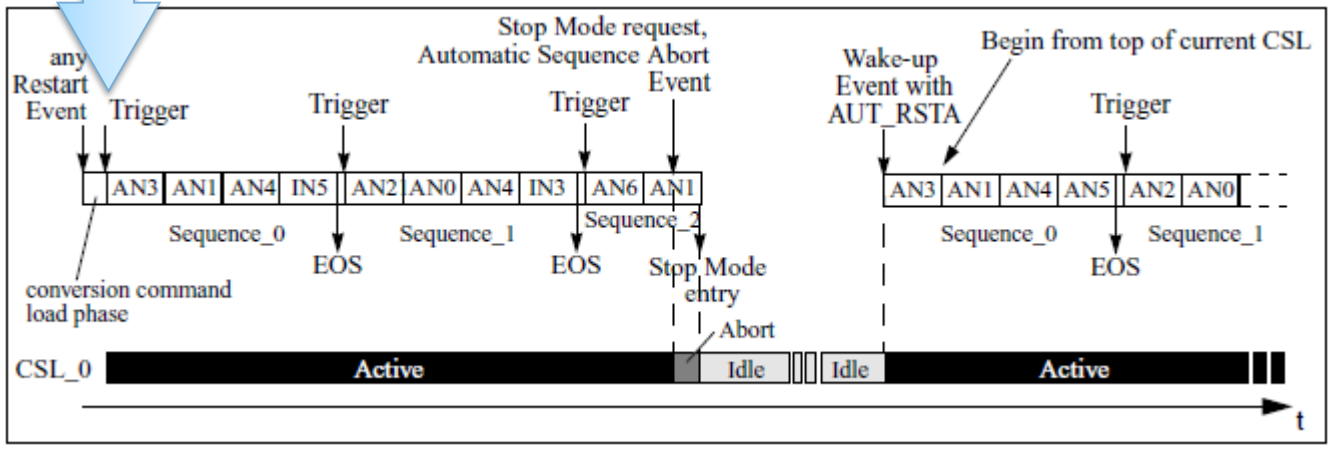
Restart Event = Trigger for first coverstion sequence



Example 2:
Trigger Mode used for periodic and timed conversion of different groups of channels in single buffer mode

ADC – Conversion Flow Restart Mode

1. Restart Event Trigger for first coverstion sequence
2. Trigger Event to start conversion



Example :
Restart Mode used for periodic and fully timed conversion (incl. Start) of different groups of channels in single buffer mode

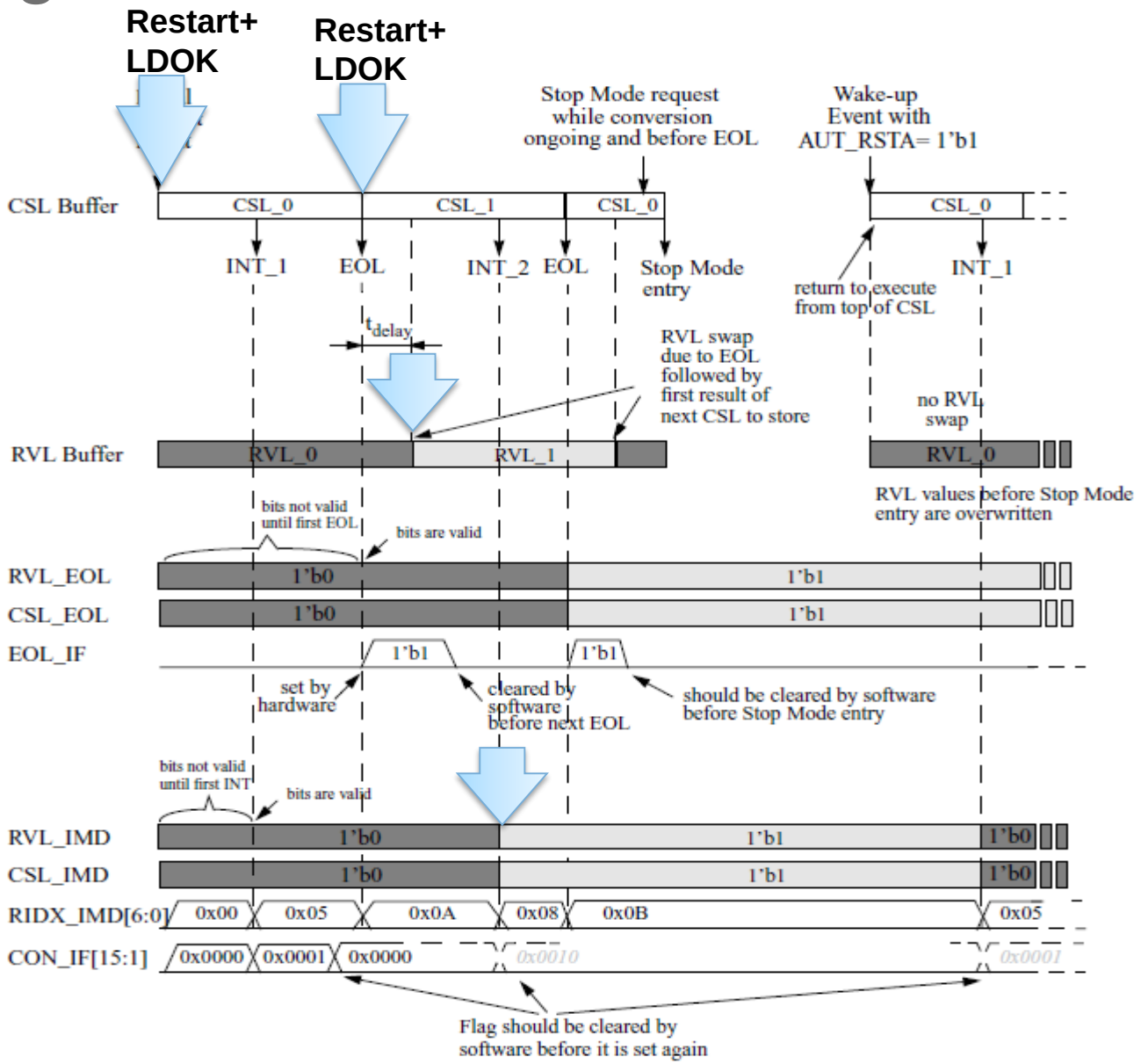
ADC – Buffer Swapping

Swap of CSL:

Requested by
- Positive edge of Internal Interface signal Restart after or simultaneously with positive edge of Internal Interface signal LoadOK
-Write Access via Data Bus to set control bit RSTA simultaneously with bit LDOK;

Swap of RVL:

Requested by
- EOL
- certain tdelay to be considered until swapping
- indicated indirectly by RVL_IMD after first INT_x



ADC – ADC Errors

- **Double bit ECC Error (DBECC_ERR):**
  - double bit ECC error occurred during conversion command load or result storage

  → ADC stops operation, ADC soft reset needed
- **Access Error (IA_EIF):**
  - During storing result illegal access error occured

  → ADC stops operation, check address definition of result buffers
- **Command Value Error (CMD_EIF):**
  - Invalid conversion command

  → ADC stops operation, check command memory
- **'End of List' Error (EOL_EIF):**
  - Command with EOL command type missing in CSL

  → ADC stops operation, check command memory
- **Trigger Error (TRIG_EIF):**
  - no Restart before trigger or trigger occurs while trigger processed or during a conversion

  → ADC stops operation
- **Restart Error (RESTAR_EIF):**

  Restart occurs after trigger and bevore EOL or abort

  →ADC continues operation
- **LDOK Error (LDOK_EIF):**

  Restart Mode: Restart occurred without Load OK

  →ADC continues operation
- **Conversion Interrupt Flag Overrun Error (CONIF_OIF):**

  Overrun occured for one of the CON_IFs

  → ADC continues operation

ADC – Example Code: ADC List initialisation

```
#pragma DATA_SEG adcLists
  volatile char ADC0CommandList[6][4] = {
  {0x40,0xD0,0x00,0x00},    // end of sequence + no int [40] , current sense channel,
  {0xC0,0xCB,0x00,0x00},    // end of list + no int [C0], VDDA voltage + HD voltage channel [CB], 4 clock
                               cycles sample time [00], reserved [00]
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00}
  };
  volatile char ADC1CommandList[6][4] = {
  {0xC0,0xCA,0x00,0x00},    // end of list + no int.[C0], VDDA voltage + phase voltage [CA], 4 clock
                               cycles sample time [00], reserved [00]
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00},
  {0x00,0x00,0x00,0x00}
  };

  volatile unsigned short ADC0ResultList[6] = {0, 0, 0, 0, 0, 0};
  volatile unsigned short ADC1ResultList[6] = {0, 0, 0, 0, 0, 0};
#pragma DATA_SEG DEFAULT
```

ADC – ADC initialisation

```
void initADC(void){

  /************* ADC0 ************************
  ADC0CTL_0_ACC_CFG = 3;       // Dual access mode (via data bus & internal signals)
  ADC0CTL_0_STR_SEQA = 1;      // Store result at abort/restart
  //ADC0CTL_1 = 0;

  ADC0TIM = ADC_TIM;           // clock: clk = fbus / (2x(reg.value + 1)) [0.25 - 8MHz]

  ADC0FMT_DJM = 0;             // left justified result data
  ADC0FMT_SRES = 4;            // 12-bit result

  ADC0CONIE_1_EOL_IE = 1;      // End of list interrupt enable

  // ADC0 Command Base Pointer
  ADC0CBP_0 = (uint8_t)((((long)ADC0CommandList) >> 16) & 0x0000FF);
  ADC0CBP_1 = (uint8_t)((((long)ADC0CommandList) >> 8) & 0x0000FF);
  ADC0CBP_2 = (uint8_t)(((long)ADC0CommandList & 0x0000FF);

  // ADC0 Result Base Pointer
  ADC0RBP_0 = (uint8_t)((((long)ADC0ResultList) >> 16) & 0x0000FF);
  ADC0RBP_1 = (uint8_t)((((long)ADC0ResultList) >> 8) & 0x0000FF);
  ADC0RBP_2 = (uint8_t)(((long)ADC0ResultList & 0x0000FF);

...
```

ADC – ADC initialisation - 2

```
// ADC0 Command/Result Offset registers
ADC0CROFF1 = 0;

ADC0CTL_0_ADC_EN = 1;        // enable ADC0
ADC0EIE = 0xEE;              // enable all errors interrupts


/************ ADC1 ***********************
ADC1CTL_0_ACC_CFG = 3;       // Dual access mode
ADC1CTL_0_STR_SEQA = 1;      // Store result at abort/restart
//ADC1CTL_1 = 0;

ADC1TIM = ADC_TIM;           // clock: clk = fbus / (2x(reg.value + 1)) [0.25 - 8MHz]

ADC1FMT_DJM = 0;             // left justified result data
ADC1FMT_SRES = 4;            // 12-bit result

//ADC1CONIE_1_EOL_IE = 1;    // End of list interrupt enable - Used only for debugging

…
```

ADC – ADC initialisation - 2

```
  // ADC1 Command Base Pointer
  ADC1CBP_0 = (uint8_t)((((long)ADC1CommandList) >> 16) & 0x0000FF);
  ADC1CBP_1 = (uint8_t)((((long)ADC1CommandList) >> 8) & 0x0000FF);
  ADC1CBP_2 = (uint8_t)(((long)ADC1CommandList & 0x0000FF);

  // ADC1 Result Base Pointer
  ADC1RBP_0 = (uint8_t)((((long)ADC1ResultList) >> 16) & 0x0000FF);
  ADC1RBP_1 = (uint8_t)((((long)ADC1ResultList) >> 8) & 0x0000FF);
  ADC1RBP_2 = (uint8_t)(((long)ADC1ResultList & 0x0000FF);

  // ADC1 Command/Result Offset registers
  ADC1CROFF1 = 0;

  ADC1CTL_0_ADC_EN = 1;        // enable ADC1
  ADC1EIE = 0x08;              // Enable Trigger Error ISR only

}
```

ADC – ADC Error handling

```
interrupt void ADC0error_ISR(void)
{
char tmpAdcEIF;

  tmpAdcEIF = ADC0EIF;
  if (tmpAdcEIF & 0x02) {              // Load Ok Error
     AdcErrorLDOK++;
     ADC0EIF = 0x02;
  }
  if (tmpAdcEIF & 0x04) {              // Restart Request Error
     AdcErrorRSTAR++;
     ADC0EIF = 0x04;
  }
  if (tmpAdcEIF & 0x08) {              // Trigger Error => Soft Reset
     AdcErrorTRIG++;
     ADC0CTL_0_ADC_SR = 1;
  }
  if (tmpAdcEIF & 0x20) {              // End Of List Error => Soft Reset
     AdcErrorEOL++;
     ADC0CTL_0_ADC_SR = 1;
  }
  if (tmpAdcEIF & 0x40) {              // Command Value Error => Soft Reset
     AdcErrorCMD++;
     ADC0CTL_0_ADC_SR = 1;
  }
  if (tmpAdcEIF & 0x80) {              // Illegal Access Error => Soft Reset
     AdcErrorIA++;
     ADC0CTL_0_ADC_SR = 1;
  }
}
```

Peripheral Introduction – Gate Driver Unit (GDU) Topology

11V LDO

supplies the LS drivers

charges bootstrap cap for the HS drivers

Voltage Monitoring

HD High Voltage Monitor @ typ. 21/27.3 V

VLS Low Voltage trip point: 6.2 .. 7V

Integrated Dividers

HD: divider 12 ; HS : divider 6

Phase Comparators

Compares HS against DCbus/2 in HW

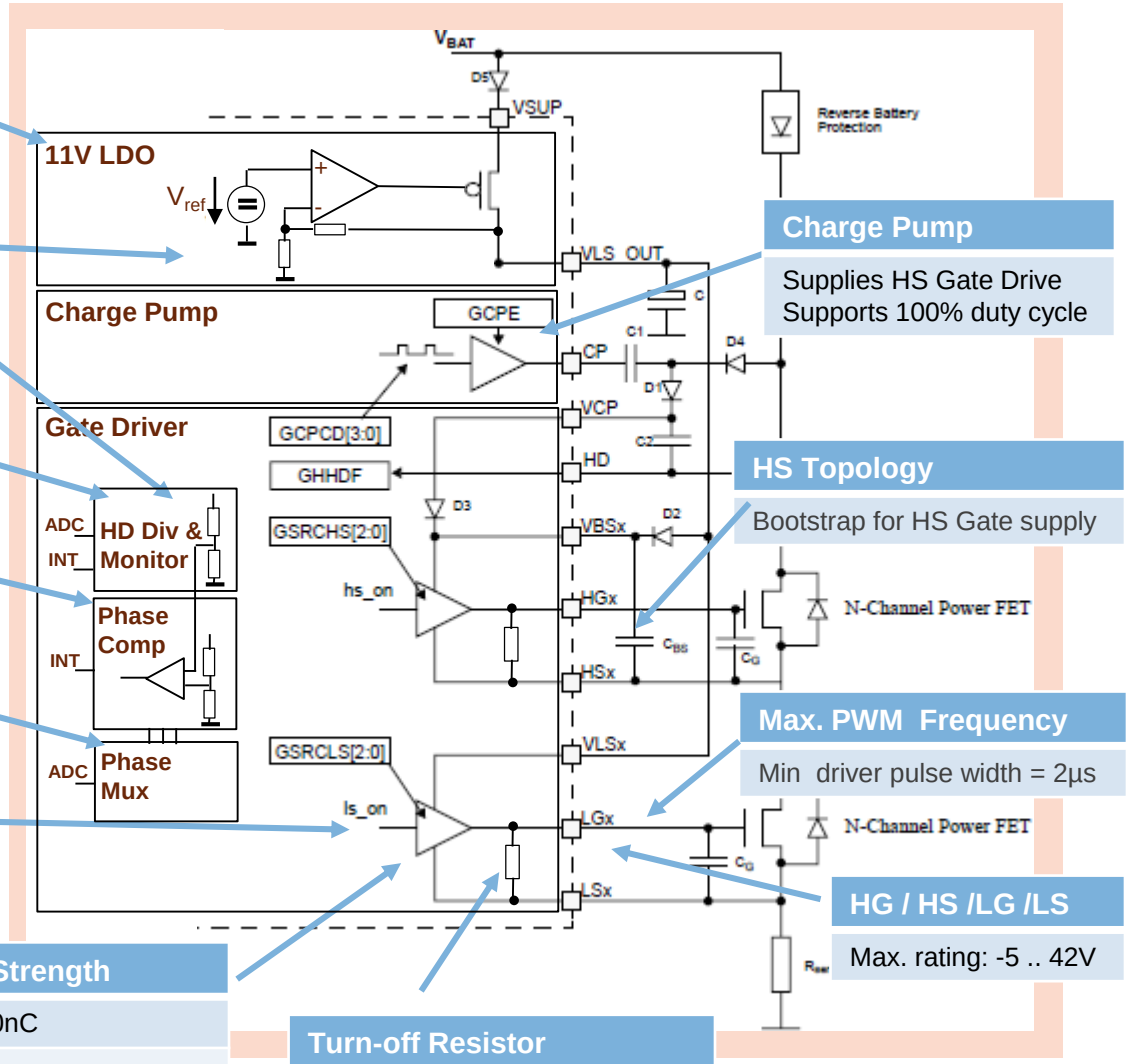
Phase Multiplexer

Switched in each sector

Slew Rate Control

Output current limitation of Iout via selectable Iref

8 selectable slew rates



Charge Pump

Supplies HS Gate Drive
Supports 100% duty cycle

HS Topology

Bootstrap for HS Gate supply

Max. PWM Frequency

Min driver pulse width = 2µs

HG / HS /LG /LS

Max. rating: -5 .. 42V

Drive Strength

Typ 100nC

Typ. 6.3 Ohm Switch on
Typ. 16 Ohm Switch off

Turn-off Resistor

80kOhm pull down integrated

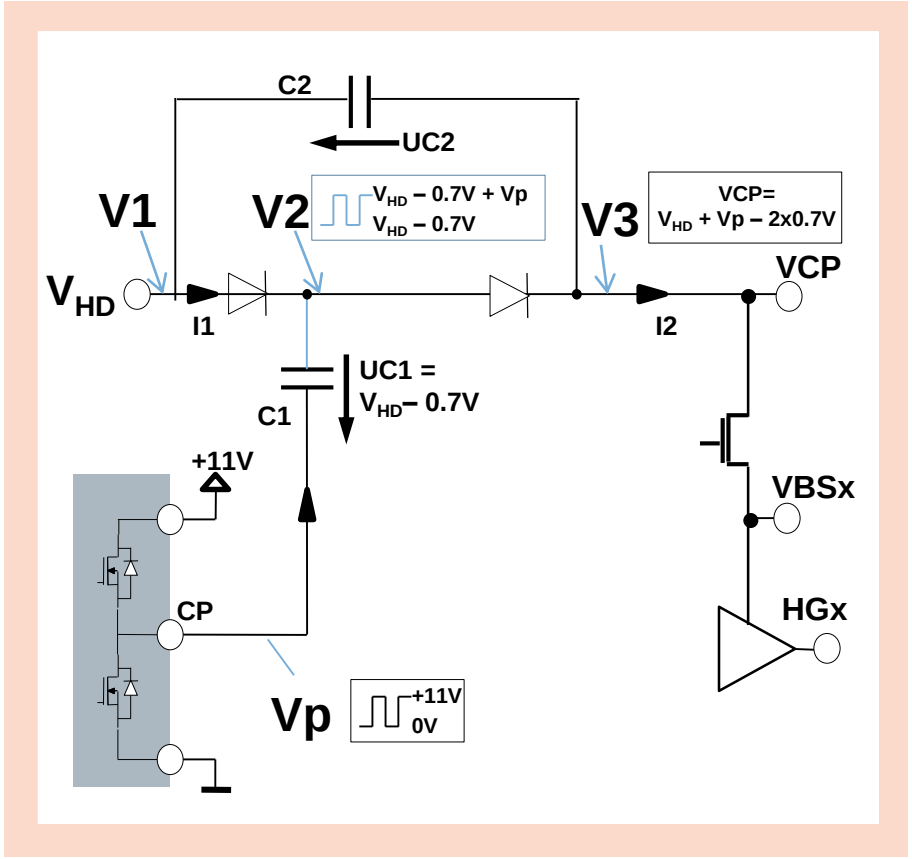
GDU – Charge pump basic characteristic

Charge pump states :

- Vp = 0
  - Load C1 to V_{HD} – 0.7V
- Vp = +11V
  - Load C2 with charge of C1
  - dUC2 = UC1 * C1/C2
  - UC2 = VHD– 2x0.7V

Characteristic Summary

- Charge pump adds fixed voltage on top of V1
  - Independent of the relation of V1 and Vp
  - If V1 = Vp it serves as a voltage doubler
- I1 = 2 x I2
- V3 ripple is minimum for C2 >> C1
  - reduces the feedthrough of V1 ripple on V3
- Lower plate of C2 should be connected to V_{HD}



V3 = V1 + Vp – 2 x 0.7V

GDU – Charge Pump Dimensioning

Component selection depends on

- selected charge pump frequency
- acceptable voltage ripple
- GDU current for the static HS Switch drive
- acceptable power dissipation (on charge pump diodes)

$$f >= \frac{I_{GDU}}{C_{pump} * V_{ripple}}$$

Example EVB board setup:

C1 = 10nF

C2 = 100nF

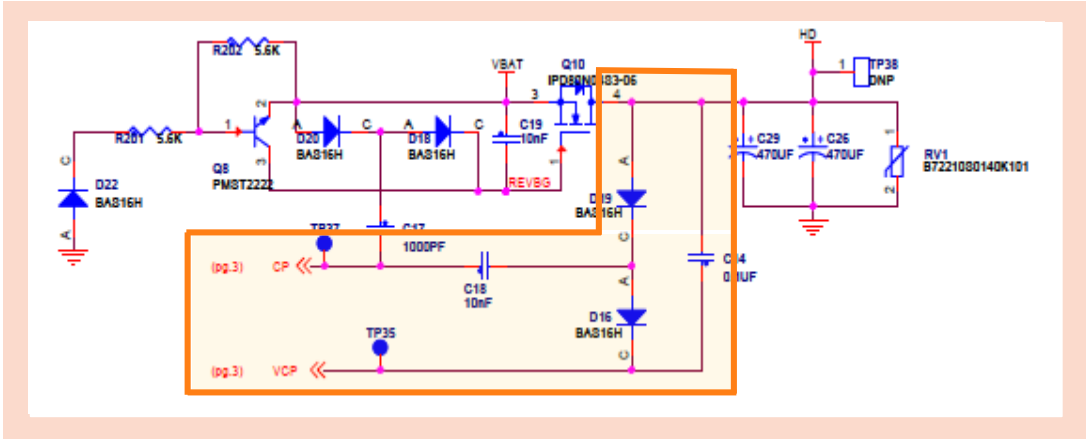
(connected to V_{HD})

f = 500kHz

I_{GDU} = 2mA

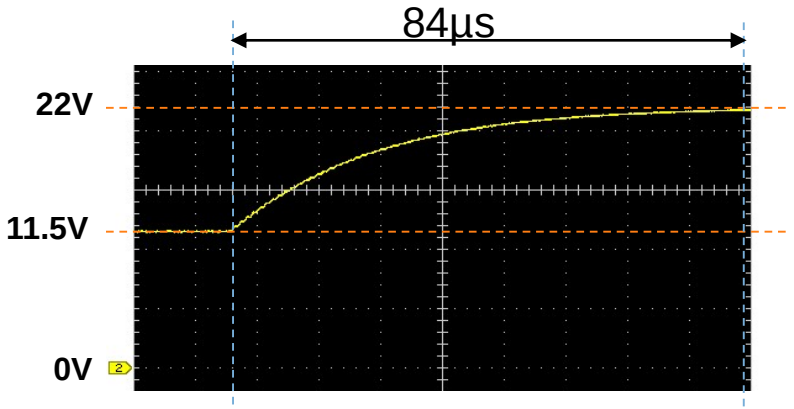
(assuming worst case of 3 HS to be switched at same time)

$$\rightarrow V_{ripple} = \frac{2mA}{10nF * 500kHz} = 40mV$$



Charge Pump startup:

Measured smooth charge pump startup on VCP @ 1.56MHz



GDU – Boost Converter

Coil Size

High frequency option allows small coils down to 10µH

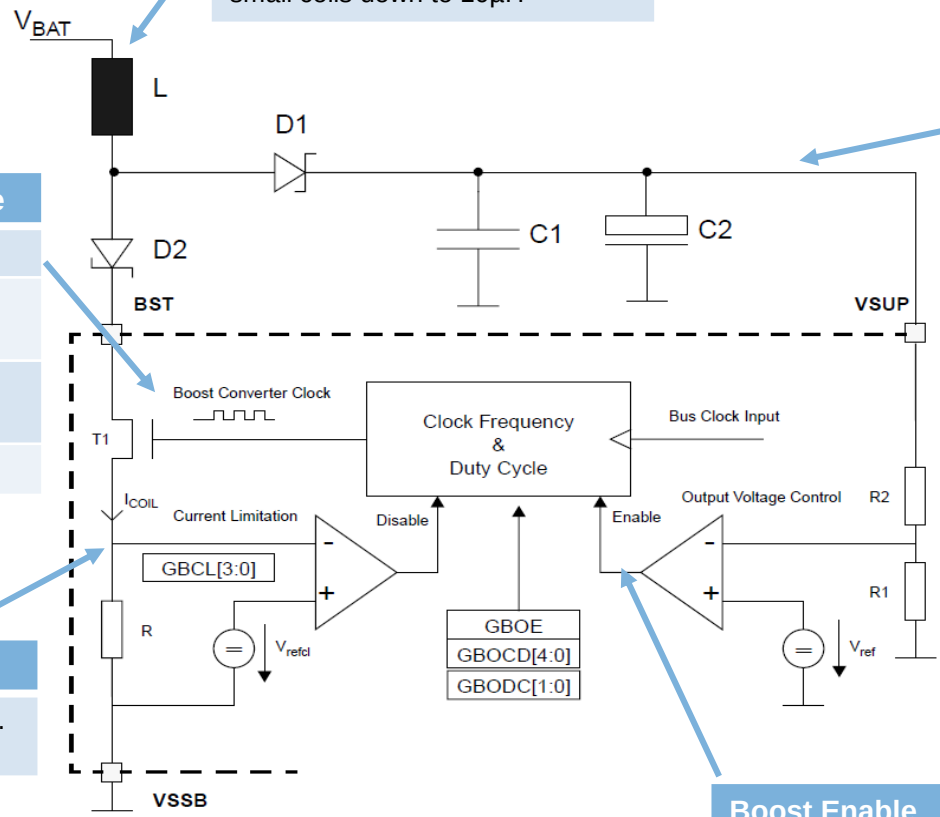
Step-up frequency /duty cycle

Wide range selectable

Optimizes dI/dt and power dissipation

Frequency range : 62.5kHz .. 12.5MHz @ 50MHz fbus

Duty cycle : 25%, 50% or 75%



Boost Function

Optional

guarantees a V_{GS} > 9V at low V_{BAT} conditions

Coil Current limitation

threshold selectable between typ. 190mA, 380mA and 560mA

Boost Enable

V_{BAT} <9.5V → Boost Converter enabled

GDU – Boost Converter

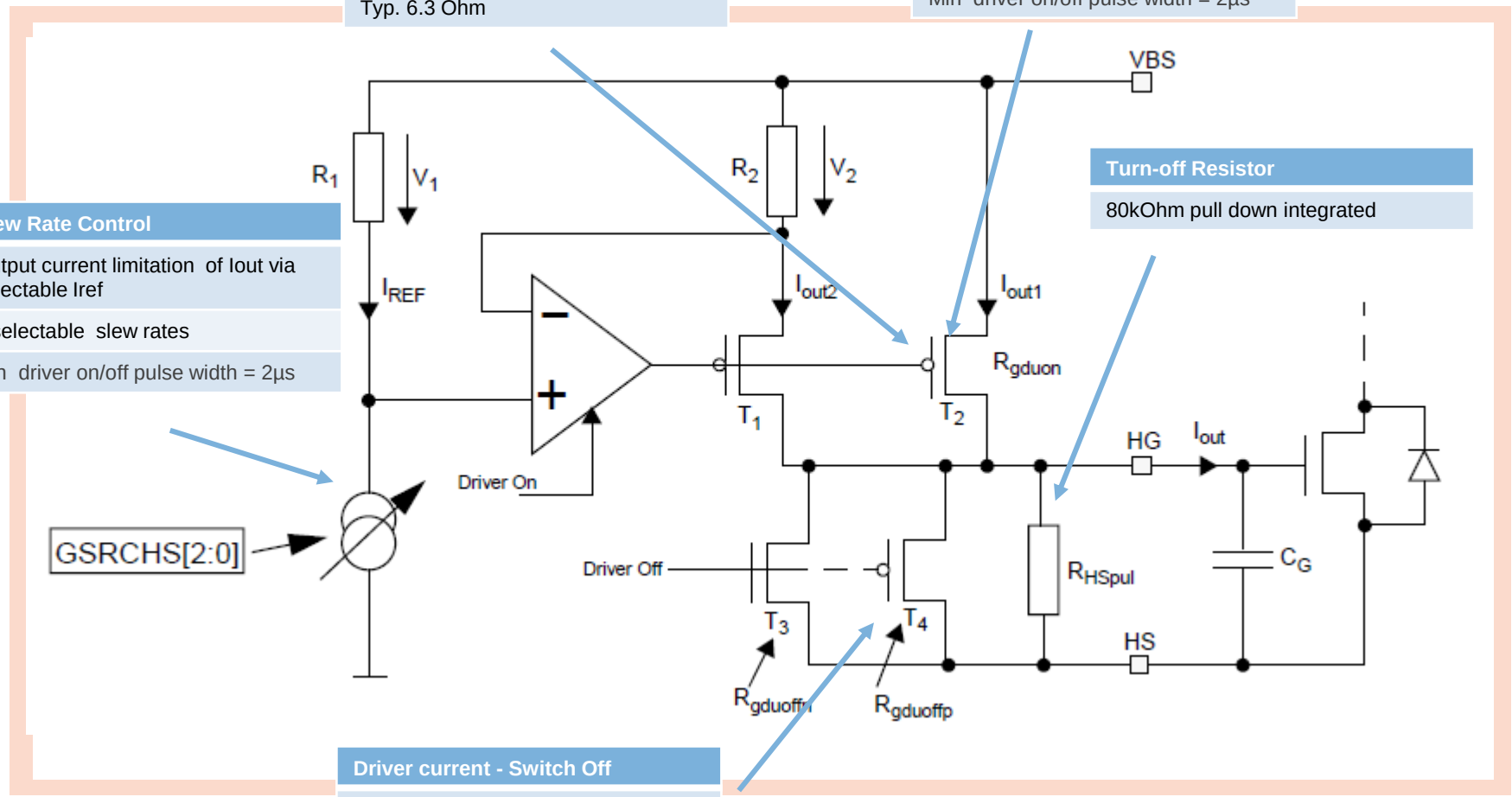
Without Boost

Vsup	MCU	GDU
20V…40V	Full	Disabled
7V…20V	Full	Enabled Vgs> Vsup – 2*Vbe (5V min)
6V .. 7V	Full	Disabled
3.5V .. 6V	Full Iddx = 25mA max if no external PNP	Disabled
<3.5V	Reset	Disabled

With Boost

Vsup	MCU	GDU
20V... 40V	Full	Disabled
9.5V...20V	Full	Boost OFF for Vsup > 11V Vgs = 9.6V
6V…9.5V	Full	Boost ON Vgs >9V
3.5V .. 6V	Full Iddx = 25mA max if no external PNP	Boost ON Vgs >9V
<3.5V	Reset	Disabled

GDU – Gate Driver Details



GDU – GDU Slew Rate Control

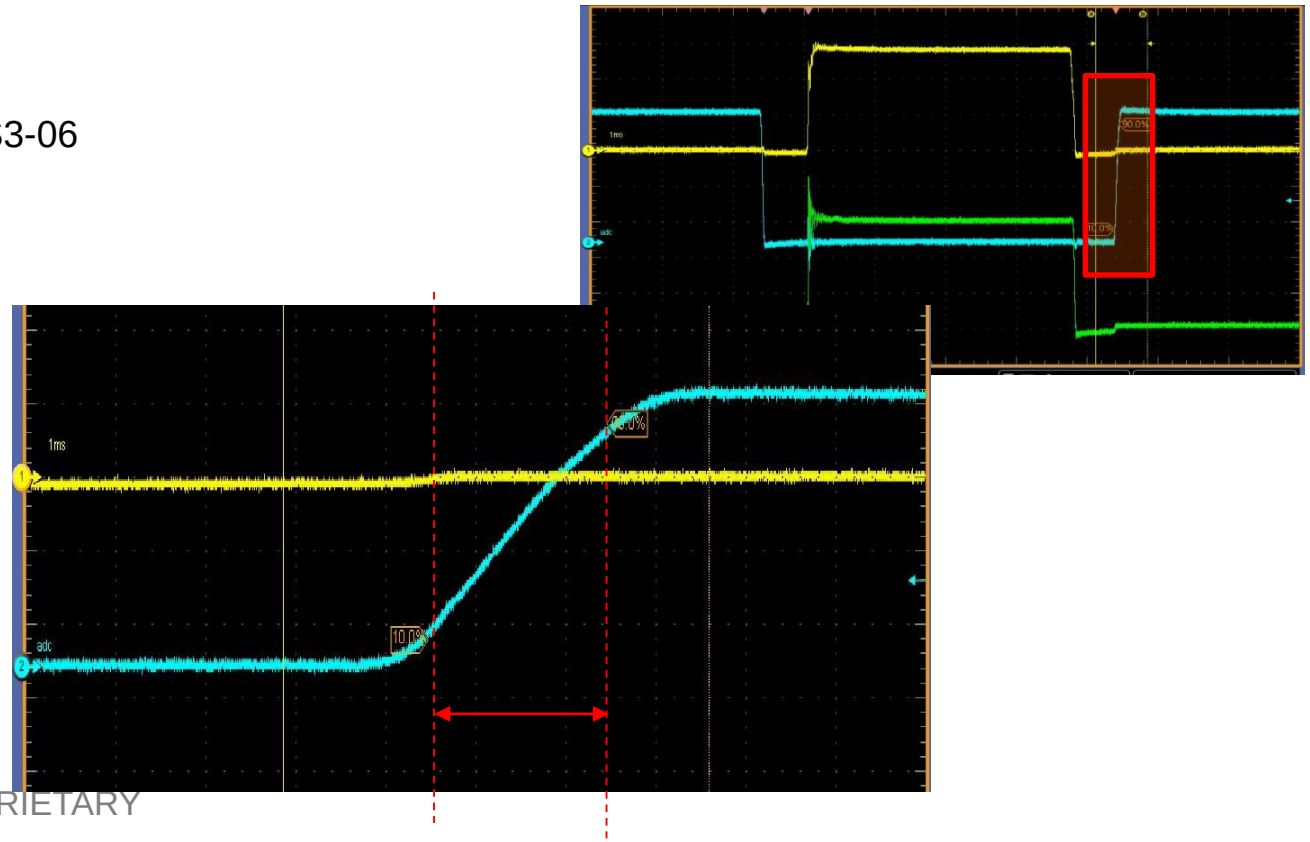
Module Base + 0x0005 — Access: User read/write(1)

GDUSRC Register

	7	6	5	4	3	2	1	0
R	0	GSRCHS[2:0]			0	GSRCLS[2:0]		
W								
Reset	0	1	0	0	0	1	0	0

Only writable if GDU Write Protection GWP disabled!

Example
measured with IPD80N04S3-06
0Ohm gate resistance
Low Side
10% to 90%

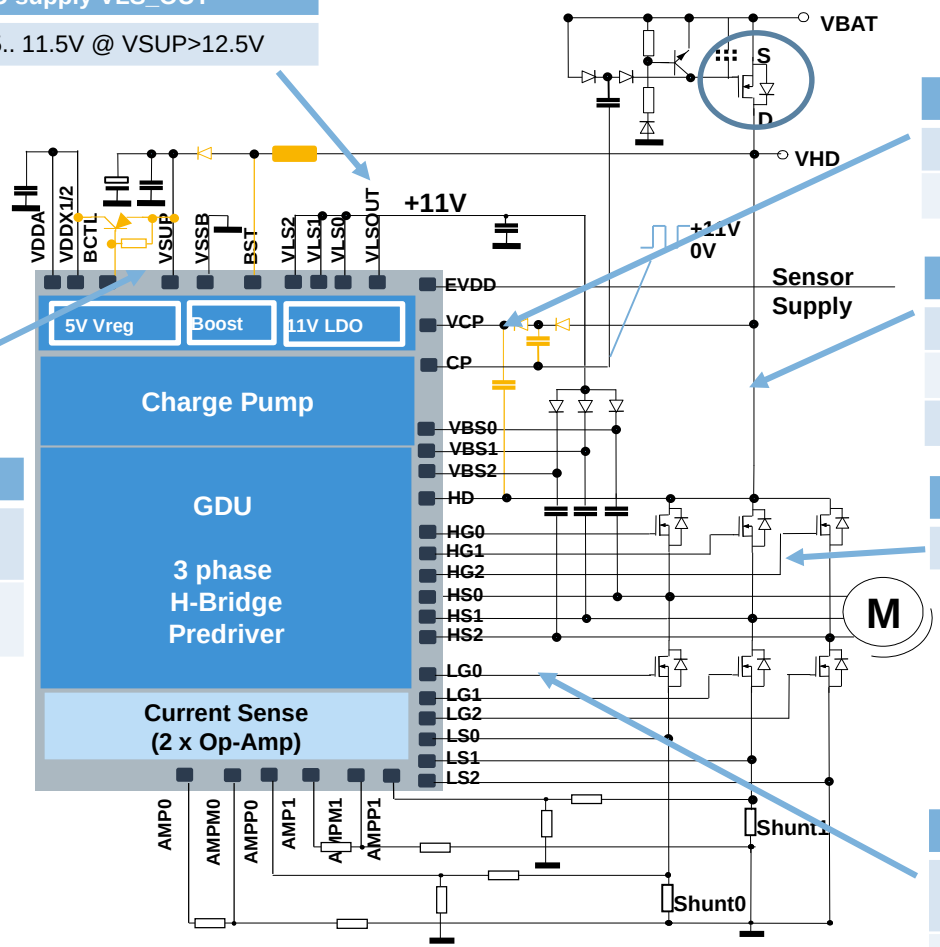


7: 101 ns
6: 104 ns
5: 107 ns
4: 109 ns
3: 112 ns
2: 136 ns
1: 188 ns
0: 396 ns

GDU – Gate Drive Unit voltage ranges

GDU supply VLS_OUT

10.5.. 11.5V @ VSUP>12.5V



Charge Pump Output VCP

Supplies HS Gate Drive

Pin Max. rating: -0.3 .. 42V

DC Link / High Side Drain (HD)

High Voltage Monitor @ typ. 21/27.3 V

Filter for High Side Monitor of typ. 2,7µs

Pin Max. rating: -0.3 .. 42V

HG / HS /LG /LS

Max. rating: -5 .. 42V

VSUP range

Full function	Boost: 3.5..20 V Without Boost: 7..20 V
Full function/ Limited time	Boost: 3.5..26V Without Boost: 7..26 V

Vgs range

Boost: 9..12 V
Without Boost: 5..12 V

Low Voltage trip point: 6.2 .. 7V

GDU – V_{DS} monitoring & Overcurrent Protection

- After turning on (any) high-side or low-side transistor, the HSx voltage is monitored

- In case of de-saturation error
  - →LS/HS switched off
  - → optional interrupt

Desaturation voltage

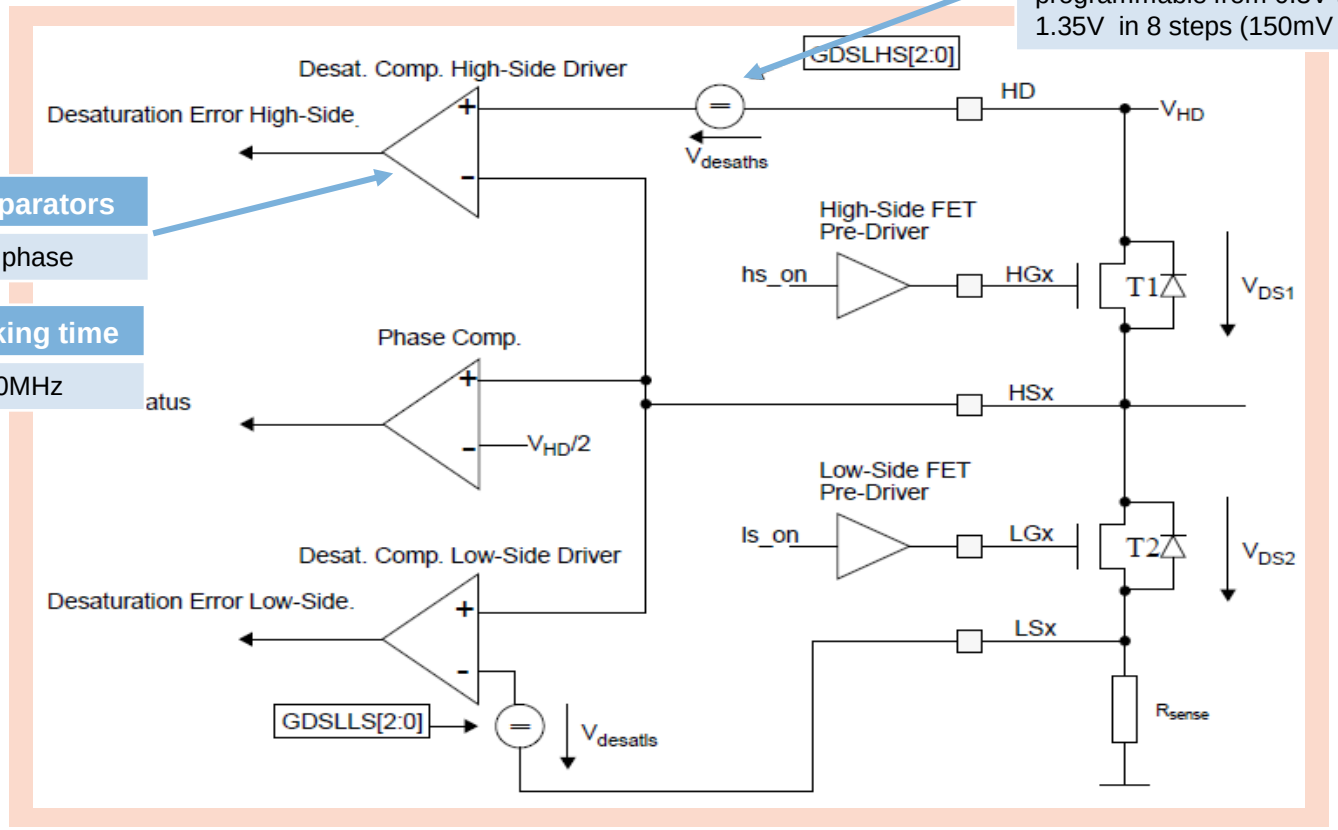
programmable from 0.3V to 1.35V in 8 steps (150mV steps)

6 Desaturation Comparators

One HS and one LS per phase

Programmable blanking time

From 80ns..4.84µs @ 50MHz



GDU – BEMF Sensing

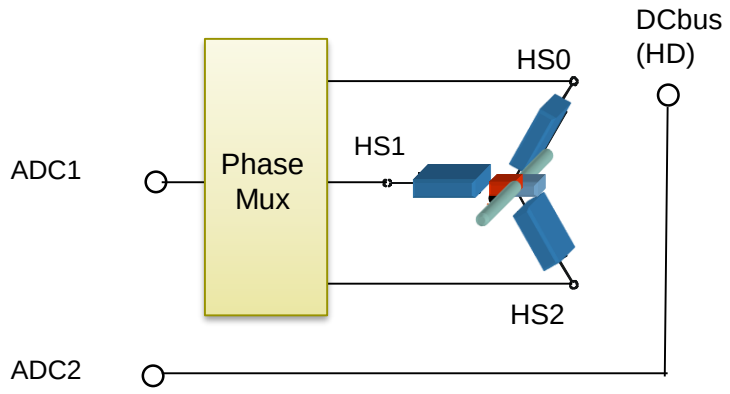
SW and HW Zero crossing topologies are both supported in S12ZVM:

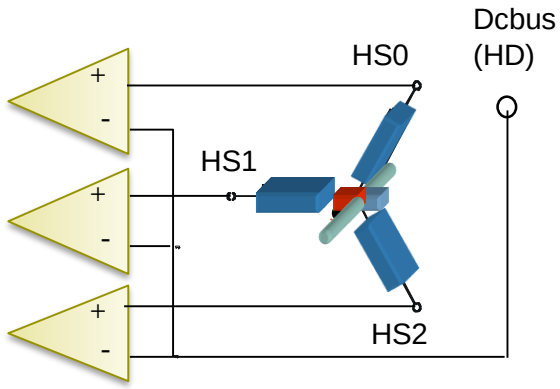
1) SW Zero crossing detection

- Integrated phase multiplexer to select the phase which is routed to the ADC internal channel
- Integrated voltage dividers for HD (DCbus) and Phase input voltages

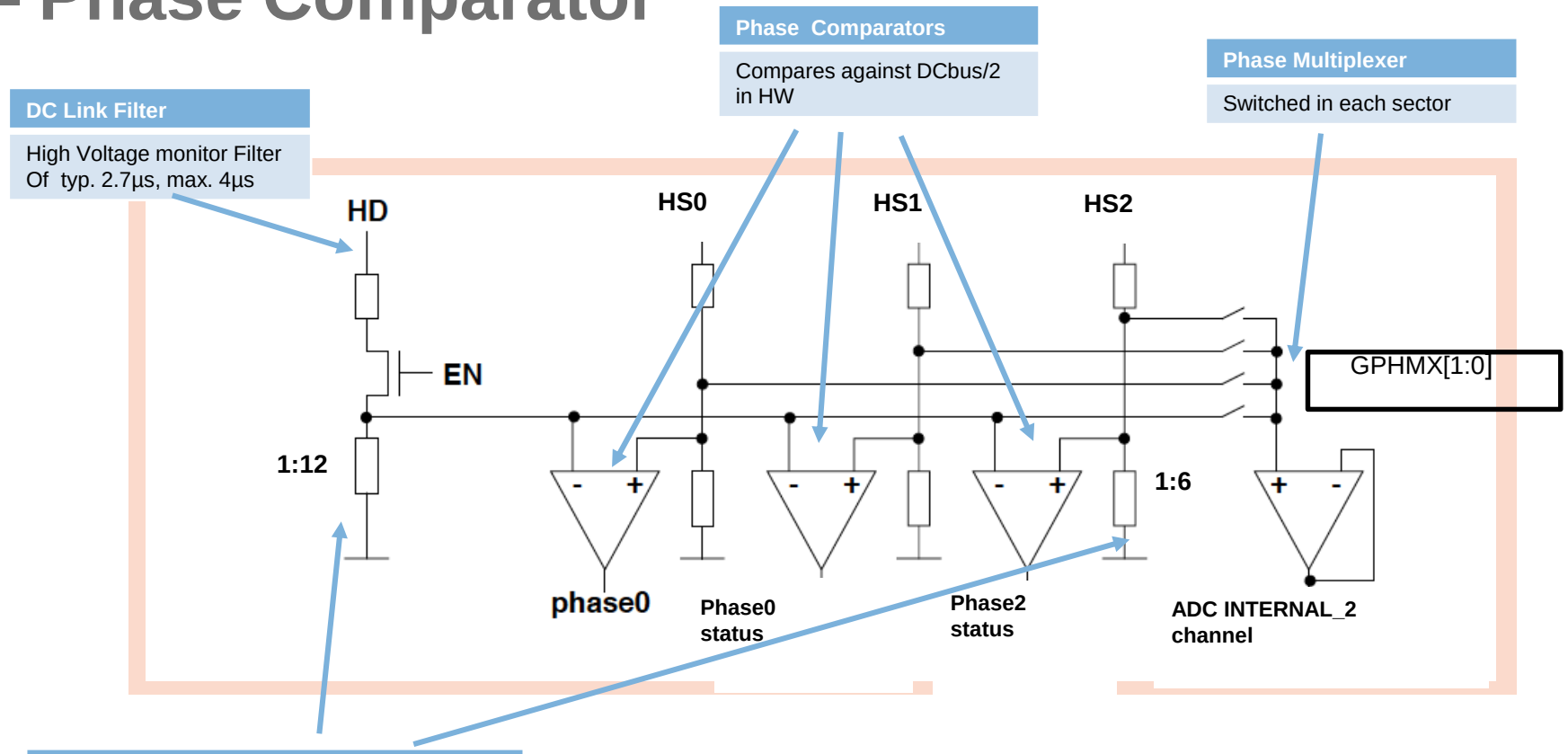
2) HW Zero crossing detection

- Integrated phase comparators to indicate if V_{HSx} is greater than $0.5*V_{HD}$
- Integrated voltage dividers





GDU – Phase Comparator



- The phase comparators indicate if phase voltage V_{HSx} is greater than $0.5*V_{HD}$
- This can be used for BEMF detection in un-driven phases
- A multiplexer selects if the supply voltage HD or any of the phase voltages is routed to an ADC internal channel

GDU – Current measurement & Overcurrent protection

Overcurrent Comparator

Flexible programmable with 6-bit DAC

Voltage range : 3.82V .. VDDA

Current measurement

Two current sense amplifiers

Supports 2-shunt systems

Measures voltage across shunt

Output voltage

Range 0 V .. VDDA

measured on ADC via external channel AMP(0/1)

Gain

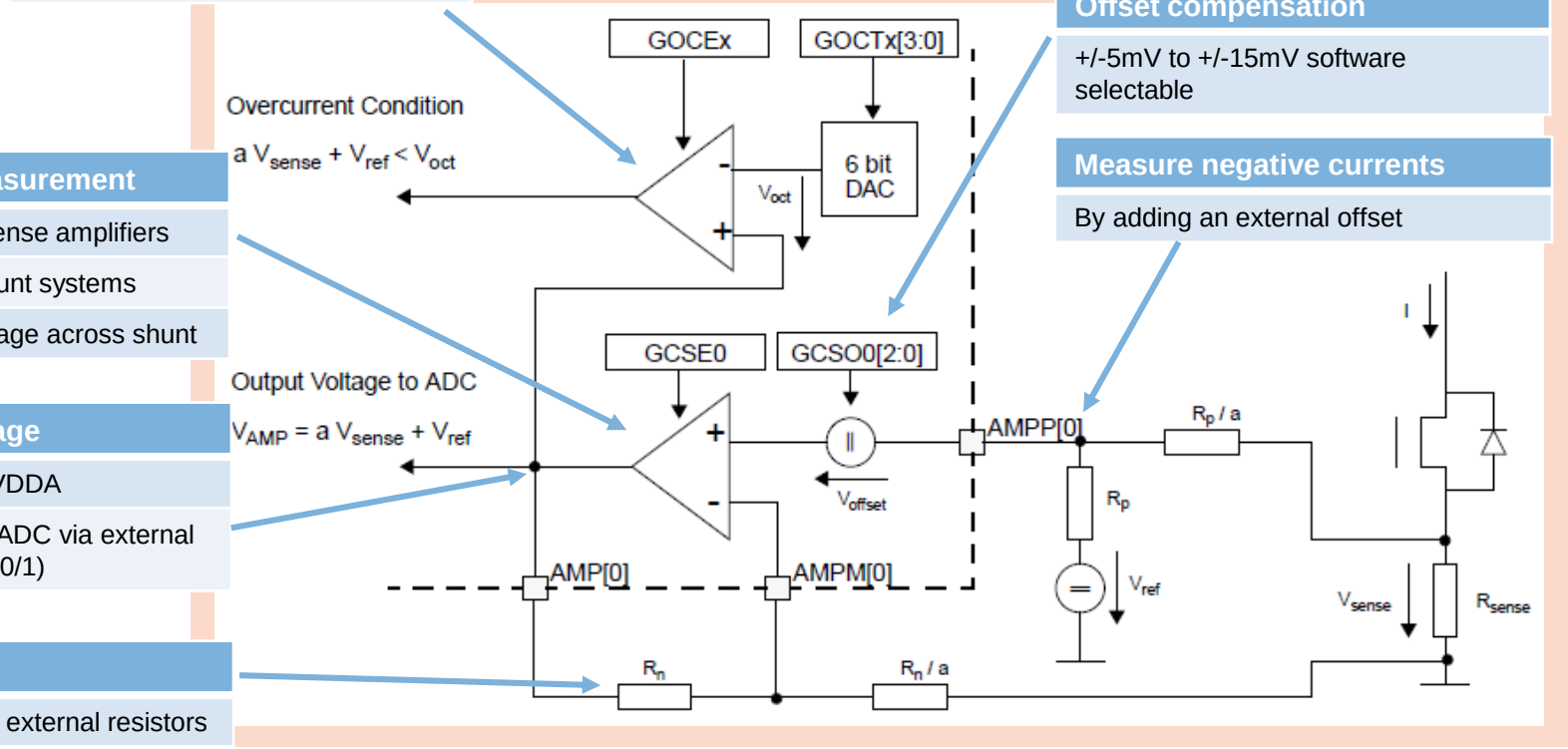
Selectable via external resistors

Offset compensation

+/-5mV to +/-15mV software selectable

Measure negative currents

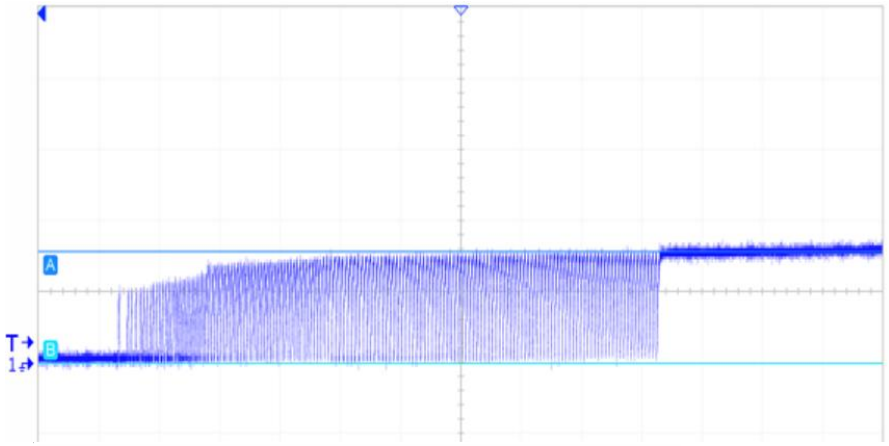
By adding an external offset



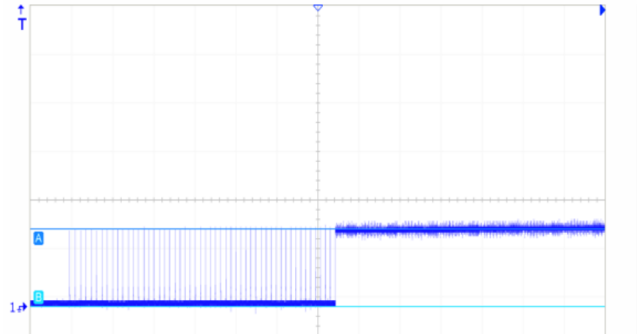
CASE SHARING

Case 1 – Some abnormal behavior @ power on or power down

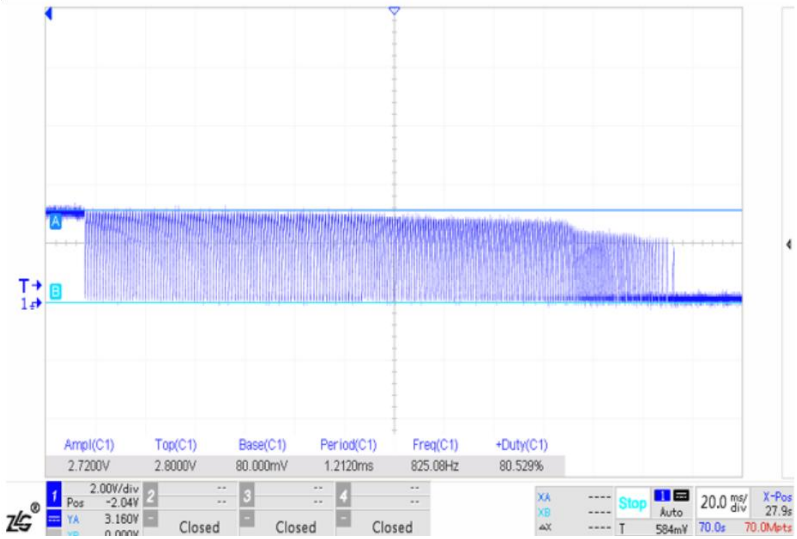
- We want to know why S12ZVL reset pin will show abnormally waveform when VSUP power on or power down at 3.8v, and at this situation, GPIO will also output waveform, we capture the power on and power down waveform on GPIO and reset pin when VSUP at 3.8v point, could you help for it?



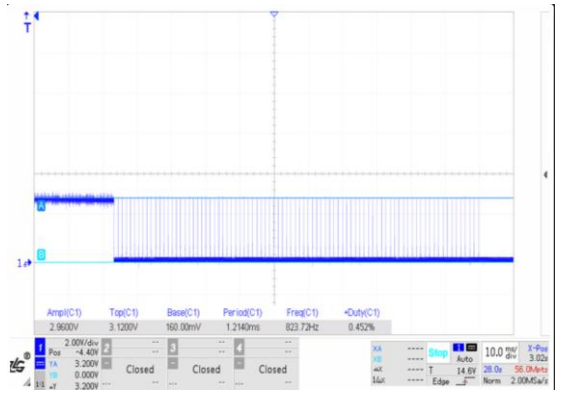
RESET PIN @Power ON



IO PIN @Power ON



RESET PIN @Power OFF



IO PIN @Power OFF

Case 1 – Solution

- *Root cause： minimum supply voltage of S12ZVL is 3.5V. If VSUP bigger than 3.5V, the silicon will start work from RESET status. But the power on process will cause supply voltage oscillate and S12ZVL jump in and jump out RESET status.*
- *If S12ZVL jump out RESET status, the customer app may work and IO will output; but if the jump in RESET status, the IO will not output. So the IO abnormal output will show.*
- *Possible Solution: customer app should monitor supply voltage after the power on. If the supply voltage is stable and bigger than 3.5V, then the app can go other tasks, no any output before the voltage stable and bigger than 3.5V. When power down, also check the supply voltage, if supply voltage small than a certain value, for example, 4.0V, stop the output.*

Case 2 – ADC TRIG error happened if set the PTU first trigger very small

- The case happened if using PTU to trigger ADC and the first trigger point is smaller than 10.
- *The root cause is ADC need 10 bus cycle maximum time window to access the first ADC command from the list.*

NOTE

In the PTU there is time window after the **reload** event assertion before the first trigger is permitted. This time can be up to 10 bus cycles.

Subsequent triggers also require a load time of 6 bus clock cycles (one trigger generator enabled) or 10 bus clock cycles (both trigger generators enabled). This defines the minimal spacing between triggers without causing a PTU trigger generator timing error.

In the ADC there is 10 bus cycle maximum time window after the **reload** event assertion to access the first ADC command from the list. In this window the ADC conversion can not be started. If the measurement is control loop related these delays are negligible due to much larger delays in the PWM-GDU-feedback loop.

In dual shunt FOC code, the first trigger point is 0x10.

Case 3 – Any tips for tracking sampling point

- Customer met some ADC sampling issue (by using PTU and PMF method), how to position the issue and help customer to solve it.

  Solution: *if can track the trigger point, the investigation become more easier.*

```
PTUDEBUG_PTUT0PE = 1;  // Enable Trigger Generation 0
PTUDEBUG_PTUT1PE = 1;  // Enable Trigger Generation 1
PTUDEBUG_PTUREPE = 1;  // Enable Reload generation to PIN
```

*Set the above register configuration, it can check the output of T0, T1 and reload signals in **debug mode**.*

it can't work in normal mode.

Case 4 – Bootstrap circuit can be delete?

- Charge pump are used to supply top MOSFET Vgs, the bootstrap circuit also used to turn on top MOSFET. Is it possible to simplify the circuit and delete the bootstrap circuit?
- *No, can't only use charge pump without bootstrap circuit. But can delete charge pump circuit if not need 100% percent turn top MOSFET on. Because the charge pump circuit can't work alone to turn on top MOSFETs.*

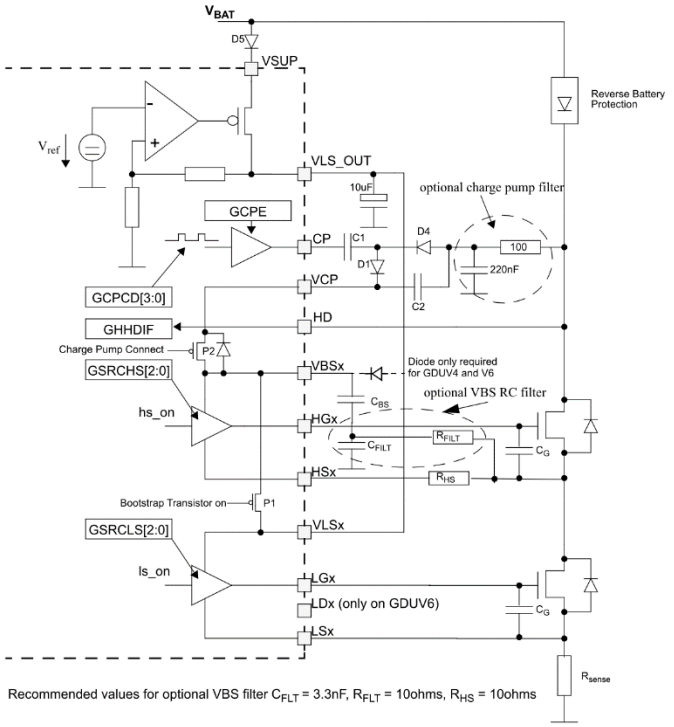
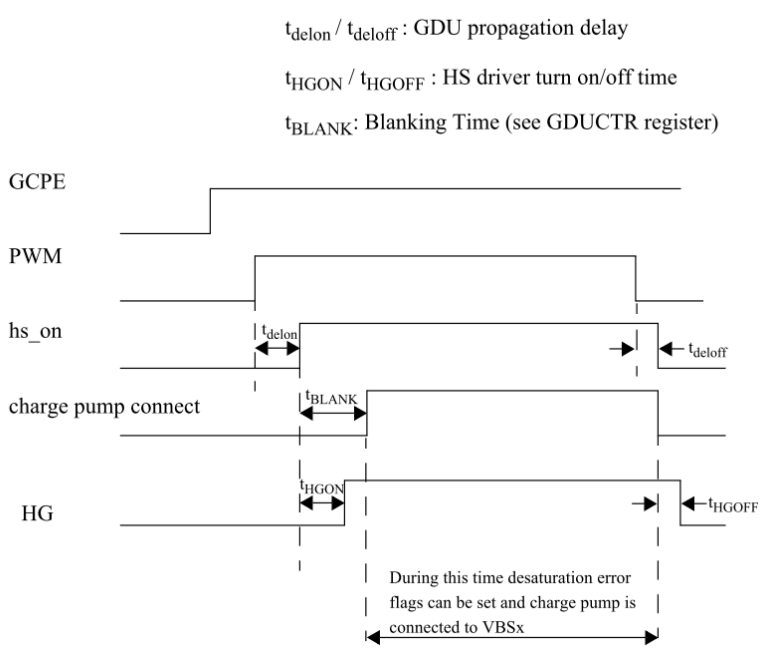


Figure 18-21. Timing Diagram Charge Pump Connect



Charge pump circuit connect has a delay tBlank which is used in desaturation detection.

so tBlank can't be zero.

SECURE CONNECTIONS
FOR A SMARTER WORLD